

A Study on the Tetrathio-TTF Compounds Unsymmetrically Substituted with Normal Alkyl Groups

A Thesis

Submitted to the University of Tokyo in Fulfillment of the Requirement for the Degree

of

Doctor of Science (Rigaku Hakushi)

by

Akihiro Otsuka

December, 1990

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1. Introduction

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1-1. Control of the Physical Properties of a Molecular Assembly

How can we "control" the physical properties of a molecular assembly? In other words, what are the requirements to obtain a molecular assembly possessing a certain "intended" physical property? The general solution of this problem can be considered to be one of our goals, and it is of course worth while trying to make any step forward in that subject.

The approach to the synthesis of a material revealing the desired properties could formally consist of the following two steps. The first step is to "design" the molecular assembly. This is no other than to make clear what kind of molecular arrangements and electronic states are essential to the physical properties in question. The second one is to "construct" actually the designed assembly from its components. This step means an intended synthesis of a molecular assembly so as to control the molecular arrangements and electronic states.

In order to design and construct a molecular assembly in such a way, it should be required not only to understand correctly and precisely the intermolecular interactions working in the assembly, but also to control them freely. One of the practical methods is to introduce chemical

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perturbations into a system and study their effects on its physical properties.

This thesis focuses on conductive organic molecular assemblies, and aims at the exploration of the new compounds in which the intermolecular interactions linking to the conducting properties could suffer chemical perturbations.

In choosing C_n TET-TTF (bis(alkylthio)ethylenedithiotetrathiafulvalene, Fig. 1-1) as the object of study, BEDT-TTF (bis(ethylenedithio)tetrathiafulvalene) cation radical salts and TTC_n-TTF (tetrakis(alkylthio)tetrathiafulvalene) are briefly looked over in the next section.

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1-2. BEDT-TTF Salts and TTC_-TTF

BEDT-TTF (Fig. 1-1) was synthesized in 1978¹⁾ in a course of the extension of TTF (tetrathiafulvalene) family.

It was not until $(\text{BEDT-TTF})_2 \text{ClO}_4 (\text{TCE})_{0.5}$ (TCE is 1,1,2-trichloroethane) was prepared in 1982^2) that this electron donor was highlighted. This cation radical salt maintained its metallic conduction and two dimensional conducting property down to 1.4 K²). It has been understood that its two-dimensional electronic property is based on its two-dimensional structural feature; the characteristic sulfur to sulfur atomic contacts along the side-by-side direction of the donor molecule³.

In 1983, $(BEDT-TTF)_2ReO_4$, the first BEDT-TTF based organic superconductor (4 kbar, $T_c=2$ K) was reported⁴). Up to now, BEDT-TTF generated more than twenty superconductors. The highest T_c organic superconductor also belongs to the BEDT-TTF cation radical salts (0.3 kbar, 12.8 K for (BEDT-TTF)_2Cu[N(CN)_2]C1⁵).

It is worth noticing that the following features are common to the conducting BEDT-TTF cation radical salts.

i) The donor molecules do not show a good planarity; the terminal ethylene groups, which belong to the six-membered ring, deviate from the C_6S_8 plane defined by the tetrathio-TTF part. The conformational disorders of the

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ethylene groups are often observed. Such situations tend to prevent the direct face to face overlappings of the donor molecule. The intermolecular interaction in the side-byside direction is as important as that along the normal of the molecular plane, or more.

ii) The concepts of "stacking column" are not necessarily suitable for describing the packing manner of the donor molecule. In most cases, the donor molecule is aligned with its long molecular axis almost parallel each other so as to produce a two dimensional conducting "sheet". This donor sheet is sandwiched in the insulating sheets consist of the counter anions, and the anion sheet is also between the donor sheets. The insulating sheet is made of discrete or polymeric ions and/or solvents. In some cases, the anions with novel structures are in situ incorporated into the salts.

iii) Analyzing the donor sheets in detail, various kinds of molecular arrangements are observed.⁷⁾ This polymorphism can give the samples of the same composition but different crystal structure, even in the same batch.

The features i) and ii) are considered to be strongly related with the two dimensional metallic state of those salts. The experimental evidences for closed Fermi surfaces (Schubnikov de Haas effect) have been observed in some BEDT-TTF salts.⁸⁾ The quasi-isotropic electronic character in

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the conducting sheet must be making a great contribution to the stable metallic state and probably to the appearance of the superconductivity.

The wide variety of packing manners of BEDT-TTF salts mentioned in iii) leads to both possibilities and difficulties to control the physical properties. BEDT-TTF molecule is considered to have an ability to adapt to its circumstances, however, the molecules (which include anionic species) are automatically assembled by themselves. As a result, unless we clarified the mechanisms or conditions of the assembly formation, or unless we were able to directly touch the organizing processes of the components, it would be impossible to control the molecular arrangements and physical properties. At this stage, we are able to get some cation radical salts but unable to know their properties (e.g. semiconductor, metal or superconductor) before they are measured.

 TTC_n -TTF is a series of tetrathio-TTF derivatives which has four normal alkyl substituents (n refers to the number of carbon atoms for one alklyl chain; Fig. 1-1).

 ${\rm TTC}_1$ -TTF was first synthesized in 1974 through a potentiostatic reduction of 2-ethylthio-4,5-bis(methylthio)-1,3-dithiolium salt.⁹⁾ A lot of its charge transfer complexes and cation radical salts have been reported so

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far, but a metallic behavior has been observed only on $(TTC_1-TTF)I_2$ (10).

In $(\text{TTC}_1 - \text{TTF})I_{2.47}$, the donor molecule is almost flat including the terminal methyl groups. The donors pile up in parallel to make a conducting column. The side-by-side interdonor interactions are prevented by the methyl groups pointing to that direction as well as by anions. Instead, relatively short sulfur to sulfur distances are observed in the direction parallel to the long molecular axis. Such a donor packing in $(\text{TTC}_1 - \text{TTF})I_{2.47}$ is suggestive of a large difference between $\text{TTC}_1 - \text{TTF}$ and BEDT-TTF in the donor's ability to make a two dimensional conducting sheet.

The elongation of the normal alkyl chains, namely, the syntheses of the new molecules of TTC_n -TTF (n=2~18) were performed.¹¹⁾ This chemical modification was regarded as the most basic and the simplest one aiming at some novel properties. The systematic investigations on TTC_n -TTF showed that its physical properties (conducting,¹²) thermal,¹³ and electronic¹⁴) and molecular and crystal structures¹⁵) depend on the length of an alkyl chain.

n dependence of melting points shows the minimum (m.p.=24.6 °C for n=4). According to a thermodynamic analysis, TTC_n - TTF can be regarded as a flexible molecule as a whole like an alkane when n≥6. This means that the cohesion is mainly dominated by the four alkyl chains in the

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large n region (n≥6).

Electrical resistivity for TTC_n -TTF decreases $(10^{10}+10^5 \, \Omega \text{cm})$ with the increase in n (1+10). Connecting with the results of structure determination (vide infra), this phenomenon has been understood to be due to the increase in carrier mobility by an effective formation of conducting path.

For small n (n=1 (phase 1), 2, 3), the C_6S_8 segment is bent in a boat-form and the four alkyl chains are directed to the same side of the molecular plane. The molecules are packed in an unfavorable manner for electrical conduction. When n is more than three, TTC_n -TTF molecule now takes a chair-form with its C_6S_8 segment flat. The four alkyl chains are symmetrically directed in parallel to the opposite side of the C_6S_8 plane (Fig. 1-2). The whole alkyl chains in the crystal are aligned in parallel, and the rest (i.e. the C_6S_8 segments) is also made to be uniformly arranged to increase the intermolecular overlap integrals.

In this case, the C_6S_8 segments are directly responsible for the intermolecular interaction which affects the conducting property. On the other hand, the alkyl chains directly affect the arrangements of the C_6S_8 segments. This means that one can control the physical properties of TTC_n-TTF to some extent by changing n.

Although TTC_n -TTF is a single component conductor, it

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can suffer a chemical perturbation from its alkyl chains and it presents a contrast to BEDT-TTF salts in which BEDT-TTF is not directly touchable.

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1-3. Scope of This Thesis

The purpose of this work is to open up the novel group of conductive organic molecular assemblies of which physical properties could suffer chemical perturbations through the medium of intermolecular interactions.

 $\rm C_{\rm n} TET-TTF$ (Fig. 1-1) compound has been selected as the object of this study, because it is expected to have the characters of its both parent molecules (see section 1-2), and to show the ability to be controlled by its alkyl chains not only in a neutral state but also in a cation radical salt. As a matter of course, it is also very interesting to investigate its physical and chemical properties at the heterogeneous systems, for example Langmuir-Blodgett films. A part of such studies by us on $\rm C_7 TET-TTF$ compounds were already presented. $^{15)}$

This thesis consists of three chapters.

In chapter 2, the syntheses of C_n TET-TTF and the properties as a single component substance are described, making comparison with TTC_n-TTF series. The molecular and crystal structures of C_1 TET-TTF are also presented in connection with its low resistivity (10⁵ Ωcm).

In chapter 3, the preparation of cation radical salts of $\rm C_{\rm n}TET\text{-}TTF$ is described in the first. The crystal

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structures, conducting and EPR properties are shown on some of C_1 TET-TTF salts which include a rare example of Sb_2F_{11} salt. The conducting properties on some C_2 TET-TTF salts are also presented.

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C _n TET-TTF	$YY = -S(CH_2)_2S, Y' = SC_nH_{2n+1}$
TTC _n -TTF	$Y=Y'=SC_nH_{2n+1}$
BMDT-TTF	YY=Y'Y'=-S(CH2)S-
BEDT-TTF	YY=Y'Y'=-S(CH2)2S-
BPDT-TTF	YY=Y'Y'=-S(CH ₂) ₃ S-
trimethylene-TTF	YY=-(CH ₂) ₃ -, Y'=H
MDT-TTF	YY=-S(CH ₂)S-, Y'=H
EOET-TTF	YY=-0(CH2)20-, Y'Y'=-S(CH2)2S-

Fig. 1-1. Structures of the compounds.

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 Syntheses and Properties of Bis(alkylthio)ethylenedithiotetrathiafulvalene(C_TET-TTF)

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2-1. Introduction

Some convenient reviews on the syntheses of TTF derivatives and their related compounds are available.³³⁾

Tatemitsu et al. first synthesized C_1 TET-TTF by the cross coupling reaction of the dithiolium tetrafluoroborates (Scheme 2-1a).²⁹⁾ They reported almost equal values of redox potentials for C_1 TET-TTF, TT C_1 -TTF, and BEDT-TTF with each other. Wu et al. also synthesized C_1 TET-TTF through the cross coupling reaction of the ketones by trimethyl phosphite, and described its melting point as 122v126 °C.³⁴⁾

After our reports on the syntheses and properties of $C_7 \text{TET-TTF}$ compounds³⁰⁾, Richard et al. synthesized $C_{12} \text{TET-TTF}$ and $C_{18} \text{TET-TTF}$ by the cross coupling reaction of the ketones according to the same procedure as ours.³¹⁾

Papavassiliou et al. also reported the three different synthetic routes to C_1 TET-TTF (Scheme 2-1b).¹⁹⁾ Although they are fundamentally based on the cross coupling reactions of the ketones and the thiones, the separations from their symmetrical products were improved with introductions of polar substituents into the intermediates. Two melting points for C_1 TET-TTF were reported by them (Scheme 2-1b), independently of our result¹⁵⁾ (79,2 \times 80.2 °C, red).

As for TTC_1 -TTF, crystallographically different two phases have been reported. The phase 1 is orange in color,

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and the C_6S_8 segment of the molecule takes a boat-form in it.^{21a)} The physical properties of the phase 1 have been extensively studied as a member of TTC_n -TTF. Endres reported that the phase 2 of free TTC_1 -TTF crystallized in red plates together with an unidentified product when an acetonitrile solution containing copper(II) acetate was evaporated on a slightly warm plate.^{21b)} The molecule is flat in the phase 2 except that two methyl groups are standing out from the plane. Any physical properties including melting point on the phase 2 has never been reported so far.

Wang et al. explained the alkyl chain length dependence of the melting temperature of TTC_n -TTF by analyzing the enthalpy and entropy changes at the melting point.^{13b)} They expressed the melting point T_m by the following equation

$$T_{m} = \frac{H_{0} + nH}{S_{0} + nS}$$
$$H \int_{T_{0}} H_{0} / H - S_{0} / H$$

where n was the number of the carbon atoms within a alkyl chain, and H_0 +nH and S_0 +nS were the enthalpy and entropy changes at the melting point, ΔH_m and ΔS_m , respectively.

n+So/S

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According to this hyperbolic function of n, $\rm T_m$ shows a decreasing curve with n in the case of $\rm (H_0/H) > \rm (S_0/S)$, while in the case of $\rm (H_0/H) < \rm (S_0/S)$, $\rm T_m$ shows an increasing curve with n. The appearance of a minimum in the melting point of TTC_n-TTF has been ascribed to the change of the difference in magnitudes between (H_0/H) and (S_0/S) as a function of n. They have interpreted it as a result of the concurrence of two kinds of interactions, which arise from the π -like electronic part and the alkyl part.

Mori et al. have calculated on the electronic states of the alkyl-substituted C_6S_8 molecules.¹⁰⁾, ^{14a)}, ³²⁾ The ratio of the atomic populations of the HOMO between the outer sulfur atoms and the inner ones (P_{out}/P_{in}) were given; 0.05 for TTC₁-TTF (phase 1) and TTC_n-TTF (n=2 and 9), 0.1 for BPDT-TTF, 0.148 for BEDT-TTF, 0.315 for EMDT-TTF, and 0.452 for TTC₁-TTF in (TTC₁-TTF)I_{2.47}. It seems that the relative importance of the outer sulfurs is increased as the π -like electrons on the C_6S_8 segment become able to spread out.

In this chapter, the syntheses, some physical, chemical, and structural properties of $C_nTET-TTF$ (n=1, 2, 4, 7, 10, 13, 16, and 18) are described and compared with those of TTC_n-TTF and BEDT-TTF. The cation radical salts of these compounds will be treated in Chapter 3.

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2-2. Syntheses of C_TET-TTF

Synthetic scheme of C_n TET-TTF is shown in Scheme 2-2. It is composed of a random coupling reaction between the ketones by triethyl phosphite (P(OEt)₂).

The experimental procedure for $C_7 \text{TET-TTF}$ is shown below as a representative. A mixture of 1.11 g (5.34 mmol) of 4,5-ethylenedithic-1,3-dithiole-2-one and 2.20 g (5.34 mmol) of 4,5-bis(heptylthio)-1,3-dithiole-2-one was warmed in 3.74 g (22.5 mmol) of freshly distilled P(OEt)₃ under argon at about 100 °C for 24 h. Addition of methanol to the cooled reaction mixture precipitated oily brown product, which was collected on a fine glass filter (G4) and washed with methanol then gave 2.20 g of oily dark brown powder. Washing the oily powder with n-hexane left BEDT-TTF as an orange powder(0.50 g) on the filter. The n-hexane filtrate was concentrated and chromatographed (silica gel, n-hexane) to give yellowish orange crystals of TTC₇-TTF (0.67 g) and a reddish orange oil of C₇TET-TTF (0.68 g).

$$\begin{split} & C_{7}\text{TET-TTF:mp=11.4}{}^{\circ}\text{C} \mbox{(reddish orange oil, yellow} \\ & \text{crystals). Anal. Found:C, 47.82; H, 6.36; N, 0; S, 46.32\%. \\ & \text{Cald for } C_{22}\text{H}_{34}\text{S}_8;\text{C}, 47.61; H, 6.17; S, 46.21\%. \\ & \text{EI-MS} \\ & \text{m/e:554}(\text{M}^+), \mbox{ 236}(\text{M}^+\text{-}C_{16}\text{H}_{30}\text{S}_3), \mbox{ 208}(236\text{-}C_{2}\text{H}_4); \\ & \text{the isotope} \\ & \text{pattern of the parent peak agreed with the calculated one.} \\ & \lambda_{max}(\lg(\varepsilon/\text{dm}^3\text{mol}^{-1}\text{cm}^{-1}) \mbox{ in CHCl}_3):302(\text{sh}, 4.09), \mbox{ 316}(4.13), \end{split}$$

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343(4.10), 385(sh, 3.48), 480 nm(sh, 2.46). IR(neat):2960(m), 2930(s), 2850(m), 1465(w), 1455(w), 1412(w), 1375(w), 1284(w), 918(w), 885(w), 772(m), 723(m) cm⁻¹. ¹H-NMR(CDCl₃, TMS, 60 MHz):δ=3.28(s, 4H), 2.80(t, 4H), 1.51(m, 20H), 0.88(t, 6H) ppm. The purity was checked by TLC and HPLC (silica gel).

The solvents used for the purification were altered depending on the solubility of the products. For n=4 and 7, C_TET-TTF is reddish orange oil at room temperature and purified only by silica gel column chromatography (nhexane). Florisil and neutral alumina were tried for adsorbent of column chromatography on C,TET-TTF, but both were found to bring some decomposition. As eluent for chromatography, n-hexane-diethyl ether was used for n=1 and 2, and n-hexane-benzene for n=10, 13, 16 and 18. Further recrystallization was performed from methanol for n=1, nhexane-benzene for n=2, and n-hexane for n=10, 13, 16, 18. The addition of charcoal had an evil effect on the recrystallization. Since the solubility of C_TET-TTF decreases in the large n region (especially n=16 and 18), the polarity of the solvent for column chromatography has been selected with a great care so as not to precipitate C_TET-TTF in the chromato column, and so as to give a sufficient separation as well. The further purification of C. TET-TTF was tried by means of HPLC (GPC, chloroform), but

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did not succeed.

The yields and melting points (mp) of $C_n^{\text{TET-TTF}}$ are summarized in Table 2-1. The yields (not optimized) were calculated assuming the complete random coupling reactions between the ketones mixed in 1:1 ratio. They were independent of the length of alkyl chains. BEDT-TTF was obtained almost quantitatively in the all cases examined.

The mp of C_4 TET-TTF has not been determined yet. It should be lower than that of C_7 TET-TTF (12°C) because C_4 TET-TTF does not crystallize in the same condition in which C_7 TET-TTF crystallizes (kept at -20 °C for two weeks). The color of C_n TET-TTF in solid state is from reddish orange to orange yellow. The n dependence of mp will be described in the next section (2-3).

To obtain the ketones, we have taken the different synthetic routes depending on the alkyl substituents (see Scheme 2-3).

For the normal alkyl groups (n=4, 7, 10, 13, 16, 18), the route (a) was successful which includes the half-opening process of 1,3,4,6-tetrathiapentalene-2,5-dione (TPD) by Na_2CO_3 with an alkyl ammonium phase transfer catalyst (Aliguat 336). This method is a direct application of Schumaker et al.'s procedure¹⁶⁾ to normal alkyl bromides. We obtained the ketones as brown liguid for n=4, 7 and as

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pale brown solid for n=10, 13, 16, 18, in good yields (67, 81, 83, 62, 73, 63% based on TPD, respectively).

The experimental procedure for n=7 is shown below as a representative. The reaction was carried out under inert atmosphere. 10.2 g (49 mmol) of TPD was placed in a threenecked flask with a condenser, a thermometer and a dropping funnel. To this flask, 17.98 g (100 mmol) of heptyl bromide, 38.53 g (95 mmol) of Aliguat 336 and 600 cm³ of benzene were added, and the mixture was decassed for 10 minutes by bubbling argon vigorously through the stirred mixture. An aqueous solution of anhydrous sodium carbonate (21.4 g (202 mmol) in 200 cm³ of water) was added dropwise to the mixture with vigorous stirring under argon for 2 h at 44046 °C. This reaction was slightly exothermic, therefore the addition rate of sodium carbonate was controlled so as not to raise the temperature over 46 °C. The color of the reaction mixture changed from pale yellow to yellowish brown. After the reaction mixture was cooled, the organic layer was separated, washed with water (200 $\text{cm}^3 \times 3$), dried over anhydrous Na_SO, and the solvent evaporated, leaving a dark brown oil (50.82 g). The crude oil was chromatographed two times (silica gel, n-hexane), yielding a deep brown liquid:15.02 g (81% based on TPD); IR(neat)2960(m), 2935(m), 2865(m), 1755(w), 1670(s), 1610(w), 1465(m), 1458(m), 1375(w), 1300(w), 1270(w), 1245(w), 1225(w), 1200(w),

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881(m), 722(w) cm⁻¹; MS, m/e 378.

For n=10, 13, 16, 18; mp(recryst.), 36.5\27.6(column), 54.7\55.3(benzene), 66.7\67.2(acetone), 72.7\73.2 °C(benzene -acetone), respectively.

The route (a) is more favorable than the route (b), because the former needs no mercury reagent. Unfortunately, this method was unsuccessful when 1,2-dibromoethane or methyl iodide was used as an electrophile in the same conditions. In the case of dibromoethane (ca. 20% yield based on TPD), the conversion of TPD into the product was incomplete (checked by TLC, IR and mass spectra), and the separation of the product from TPD was difficult due to a similar solubility. In the case of methyl iodide, there was one more difficulty on the reaction temperature (40~46 °C) which is almost equal to the bp of methyl iodide (42 °C).

As for the small alkyl derivatives (R=Me or Et, RR=-CH₂CH₂-), we have taken the route (b) which starts from a zinc complex synthesized by a known method¹⁷⁾ from carbon disulfide. The thiones were directly obtained from the zinc complex in 70 95 yields, and they were converted to the ketones by Hg(OAc)₂ in ca. 90% yields.

The experimental procedure for n=2 is shown below as a representative. 5.00 g (5.30 mmol) of $\text{TBA}_2[\text{Zn}(\text{dmit})_2]$ and 28 cm³ of acetone (dried over anhydrous CaSO_4) was mixed in a suspension under argon. To this red suspension, 3.6 g

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(23.1 mmol) of ethyl iodide was added all at once (slightly exothermic), and stirred for 12 h in the dark at room temperature. The resulting deep green solution was evaporated to dryness, column chromatographed (silica gel, n-hexane:CH₂Cl₂=1:1), yielding a brown yellow oil:2.56 g (94.8% based on the zinc complex); IR(neat)2973(m), 2923(m), 2865(w), 1448(m), 1421(w), 1375(w), 1259(m), 1067(s), 1035(m), 967(w), 888(w), 762(w), 736(w), 515(m) cm⁻¹; MS, m/e 254.

A mixture of 6.42 g (25.22 mmol) of 4,5-bis(ethylthio)-1,3-dithiole-2-thione, 8.07 g (25.32 mmol) of Hg(OAc)₂, 80 cm³ of chloroform, and 80 cm³ of acetic acid was refluxed for 5 h. The color of the reaction mixture changed from yellow to yellowish green, dull green, dark green, then to black. After the mixture was cooled, black powder of HgS was filtered off $(Na_2SO_4 \text{ over celite})$ by suction. The yellow filtrate was neutralized $(Na_2CO_3 \text{ aq.})$, washed with water, dried over anhydrous MgSO₄, and the solvent evaporated, leaving a brown yellow oil:5.85 g (97.3% based on the thione); IR(neat)3324(w), 3270(w), 2976(s), 2925(s), 2868(m), 2825(w), 1825(w), 1760(s), 1668(s), 1613(s), 1478(s), 1448(s), 1423(s), 1376(s), 1259(s), 1122(m), 1056(m), 1039(m), 996(m), 966(s), 885(s), 765(m), 739(m), 671(w), 644(w), 552(m) cm⁻¹; MS, m/e 238.

For n=1 and RR=-CH2CH2-, the ketone was recrystallized

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from diethyl ether and ethanol, respectively; mp, 57.2 \circ 57.7 and 127 \circ 128.5 °C, respectively.

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2-3. Melting Points of C_TET-TTF

The melting points of C_n TET-TTF are shown in Fig. 2-1 together with those of TTC $_n$ -TTF and 4,5-bis(alkylthio)-1,3-dithiole-2-one.

In the case of TTC_{n} - TTF^{13} , it has been understood that the region of n is divided into the three (1, 2 and 3). In the region 1 (1≤n≤4), the central C_6S_8 segment govern the molecular packing, and the alkyl groups work only to disturb the attracting force among the molecules as n increases. In the region 3 (n≥6), the molecular packing is mainly dominated by the alkyl chains as if TTC_n - TTF is a flexible molecule like a n-alkane (C_nH_{2n+2}), and the intermolecular cohesion increases with increase in n. The region 2 is the intermediate one, and a minimum of the melting points is observed in this region (section 2-1).

It is noteworthy that such "V-shape" correlation between the melting points and the lengths of n-alkyl chain within a molecule is also observed on unsymmetrical molecules. Figure 2-2 shows the n dependence of the melting points and boiling points for normal alkyl substituted benzenes $(Ph-C_nH_{2n+1})$.⁶⁸⁾ The boiling points increase monotonically with increasing n. This suggests that in the boiling process, the increase of n merely means the increase of the molecular weight. On the other hand, a minimum

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appears in the n dependence of the melting points in common with TTC_n -TTF. Similar behavior of the melting points with n is known for 1- or 2-n-alkyl naphthalenes¹⁸⁾. Figure 2-3 shows the melting and boiling points of n-alkanes $(C_nH_{2n+2})^{68}$, 69) for comparison.

The melting points of C_n TET-TTF look to obey the similar n dependence to TTC_n -TTF. The melting point decreases with increasing n in the small n region, then, it shows a minimum (at $3 \le n \le 6$), and at n 7 it quickly increases as n increases. The similar behavior is observed on one of its coupling moieties, 4,5-bis(alkylthio)-1,3-dithiole-2-one.

 $\rm C_n TET-TTF$ tends to show lower melting points compared with $\rm TTC_n-TTF$ at the same n. This is ascribable to both a decrease in the number of alkyl chains for a molecule and a reduction in the symmetry of a molecule (the enthalpy change at mp for C_7 TET-TTF is about 7.3% of that for TTC_7-TTF, and entropy change is 8.1%, for example). In spite of such a drastic difference in the molecular structure, both compounds look to give their minima of melting points in almost the equal n region. This suggests a great significance of a role of the non-alkyl part of the molecule in the solid state.

The appearance of the minimum in the n dependence of the melting points could have a general meaning that another

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characteristic interaction works in the solid besides the interactions by n-alkyl groups. In the above mentioned systems, the another interaction should be based on the π electronic segments.

For C, TET-TTF, there might be more than three phases in view of the melting points. Wu and Zheng described its melting point as 122v126 °C (purified by silica gel chromatography and recrystallized in hexane).34) Papavassiliou and co-workers have reported the melting points (64, orange and 75~76 °C, red)¹⁹⁾ which are different from the value of Wu et al.s' and ours (80.2~81.2 °C, red). They obtained the value of 64 °C when C1TET-TTF was recrystallized from n-hexane including a slight amount of chloroform²⁰⁾. We have recrystallized from n-hexane:diethyl ether=4:1, acetonitrile, or methanol, and the melting points have converged to ca. 80 °C regardless of the color of the crystals. When the product was crude or it was recrystallized from cyclohexane, we detected the mp of 70~76 °C. Two phases are reported for TTC1-TTF by structure analyses²¹⁾, and TSeC₁-TTF by mp²²⁾, resistivity²³⁾ measurements and structure analyses²⁴⁾.

Anyway, the melting points of $C_n TET-TTF$ change depending on n. The molecular arrangement is expected to be controlled in the solid state as a function of the relative importance between alkyl groups and the rest.

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2-4. Electrical Resistivities of C_TET-TTF

The resistivities were measured by a two-probe or a quasi-four-probe dc-method using 10 or 20 µm-diameter gold wires with silver paste (Du Pont 4922) or gold past (Tokuriki 8560) as electrical contacts.

The samples were mounted in a glass cell (Fig. 2-4). To check the influence of oxygen, some measurements were performed on C. TET-TTF and BEDT-TTF single crystals under a reduced pressure generated by an oil diffusion pump with liquid nitrogen traps. Almost no change of resistivity was observed even after the vacuum was maintained for more than 12 h. Therefore, the most measurements were done under ambient pressure of nitrogen gas after exchanging the atmosphere in the cell several times. The temperature was controlled between -15 and 60 °C by immersing the cell covered with aluminum foil into a water-ethylene glycol bath, and it was measured by a copper-constantan thermocouple placed just near the sample into the cell. The ohmicity was always confirmed, and the ranges of sensors (ammeter or voltmeter) were selected so as not to affect the measurements.

Figure 2-5 and Table 2-1 show the dc-electrical resistivities of C_n TET-TTF together with that of BEDT-TTF at room temperature. The data on TTC_-TTF¹² are also plotted

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on the same figure for comparison.

For n≥2, the resistivities of $C_n^T \text{ET-TTF}$ decrease as n increases, then look to converge into a value of $10^6 \sim 10^7 \ \Omega \text{cm}$ with compaction pellets. Especially in the case of $C_{10}^T \text{ET-TTF}$, its value of $1.0 \times 10^6 \ \Omega \text{cm}$ in compaction is comparable to that of single crystal of $\text{TTC}_{10}^- \text{TTF}$ (3.7×10⁵ Ωcm^{12}). Such an n dependence of resistivity, in which the resistivity decreases as n increases, has been already observed on $\text{TYC}_n^- \text{TXF}$ series (Y=sulfur, selenium or tellurium for X=sulfur; Y=sulfur or selenium for X=selenium) and has been understood as "molecular fastener effect" (section 1-2).

 $\rm C_n TET-TTF$ has only two normal alkyl chains, and the $\pi-$ electronic segment is placed at the other end of the molecule. This forms a striking contrast to $\rm TTC_n-TTF$ in which the $\rm C_6S_8$ segment is placed at the center of the molecule. It is not difficult to imagine that the four alkyl chains fasten up the central $\rm C_6S_8$ $\pi-$ electronic system so as to make a conduction path in the crystal of $\rm TTC_n-TTF$. In the case of $\rm C_n TET-TTF$, such a concept of "fastening" by alkyl chains might be unsuitable for the explanation of its low resistivity considering its molecular skeleton. Of course the structure analyses on single crystals of $\rm C_n TET-TTF$ (for n≥10) are necessary to understand what happening.

Since the single crystals of C₁₀TET-TTF have not been obtained, we have conjectured its rough molecular packing by

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means of powder X-ray diffraction. Figure 2-6 shows a part of the diffraction pattern for C_{10} TET-TTF. There exists a series of diffraction peaks (n=1 \sim 6) which corresponds to a repeating unit of 38 Å. Considering that TTC_{10} -TTF⁵⁸) has a distance of d_{010} =32.77 Å between the ac planes, it is likely that C_{10} TET-TTF also crystallizes to form a sheetlike structure in which the molecules are arranged in a head to head manner (see Fig. 2-7).

If it was the case that $C_n \text{TET-TTF}$ (n210) is packed such as Fig. 2-7 (b), its low resistivity should be ascribed to the substantial packing arrangement of the C_6S_8 segment with ethylene group in the crystal and not to so-called "a fastener effect". Since the flatness of the C_6S_8 segment is considered to be poor on the analogy of $C_1 \text{TET-TTF}$ (section 2-5) and $C_7 \text{TET-TTF}$ (Fig. 2-8), the interactions in the sideby-side direction of the molecule must play an important role in the electrical conduction compared with $\text{TTC}_n \text{-TTF}$.

Single crystals, which have been obtained for n=1, 2 and BEDT-TTF, show the resistivities smaller by a factor of almost two than those of their compaction specimens respectively. The remarkable fact is that C₁TET-TTF single crystals show the smallest resistivity among these compounds. The value of $\rho_{\rm rt}$ =5.4×10⁵ Ω cm is nearly equal to that of TTC₁₀-TTF (3.7×10⁵ Ω cm¹²) which is the smallest one among the single component organic semiconductors made from

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carbon, sulfur, and hydrogen only. This implies that C_6S_8 segment with ethylene group has a potential ability to produce a conductor by itself, without the assists by long alkyl chains. BEDT-TTF single crystals also show the relatively small value of $2.6 \times 10^7 \ \Omega \text{cm}$.

In the case of TYC_n -TTF (Y=tellurium¹²), 25) or selenium²³), the molecule of n=1 tends to give the crystal of high electrical conductivity as much as that of its large n derivatives. It was revealed that characteristic tellurium atomic contacts play an important role in TTeC₁-TTF single crystals.²⁵)

 $\rm C_1 TET-TTF$ dose not contain the larger chalcogen atoms than sulfur, therefore the character of the molecule is expected to come to the fore even in its assembly. The molecular and crystal structures of $\rm C_1 TET-TTF$ are described in the next section in comparison with those of BEDT-TTF and TTC_-TTF.

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2-5. Molecular and Crystal Structures of a Low Resistivity Single Component Organic Conductor; $\rm C_1\,TET-TTF$

X-Ray crystal structure analysis was carried out for C_1 TET-TTF single crystals. The diffraction data were collected at room temperature by use of an automated fourcircle diffractometer, Rigaku AFC-5 with a graphite monochromated Mo radiation (Mo Ka =0.71069 Å). Crystallographic data are listed in Table 2-2. Crystal structure was solved by a direct method using MULTAN program system and was refined by the full-matrix least-squares program. Anisotropic temperature factors were used for the refinement of the non-hydrogen atoms. The final atomic parameters are listed in Table 2-3.

Molecular Structures

Crystallographically independent two molecules (I and II) are observed in the crystal. The molecular structures and bond lengths of them are shown in Fig. 2-9 together with the numbering of atoms. The C_6S_8 segment of the both molecules takes a boat-form (bending angles are 13.3 and 10.0° for I, 17.5 and 5.5° for II, respectively, Fig. 2-10).

We can point out delicate differences between I and II on their outer alkylthic groups. For useful information, the molecular side views of TTC_1 -TTF (phase 1)^{21a)}, TTC, -TTF

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(phase 2)^{21b)}, and BEDT-TTF²⁶⁾ are shown in Fig. 2-11.

One of the two methyl groups of II (Fig. 2-10) stands almost normal to the molecular plane, but another methyl carbon lies in that plane. On the other hand, both methyl carbons of I are placed in the intermediate positions between them. It is interesting to notice that the conformations of methylthic groups of I resemble those of TTC₁-TTF (phase 1), and those of II resemble those of TTC₁-TTF (phase 2), respectively.

Such structural correlations to the parent molecule are also recognized on ethylenedithio groups. The both conformations in I and II (Fig. 2-10) exist in one molecule of BEDT-TTF.

Consequently, we observe all of the conformations of the alkylthio groups, which are known in TTC_1 -TTF (phase 1 and 2) and BEDT-TTF, in one crystal of C_1 TET-TTF. This may be quite natural, considering that C_1 TET-TTF is a hybrid molecule between TTC_1 -TTF and BEDT-TTF. However, if the present crystal is a mixed crystal of the molecule I and II, not only the respective pure crystals of I and II but also some novel structures may be obtained depending on the experimental conditions.

The bending of the C_6S_8 segment such as Fig. 2-10 might be a disadvantageous to getting a electrical conductor, because the extension of the π -orbitals' conjugation might

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be reduced, and because the molecular arrangement might result in a looser packing.

As for the electronic states of a molecule, it is worth noticing the extended-Hückel molecular-orbital calculations on TTC_n -TTF (n=1, 2, and 9) with the geometry in its real crystal^{14a)}. They indicate that the molecular-orbital energies hardly depend on whether the C_6S_8 segment is bent or flat. This result might agree with the fact that the redox potentials of TTC_n -TTF in solution are independent of n^{11} . Accordingly, the large differences in the solid state properties between TTC_1 -TTF and TTC_{10} -TTF should be ascribed to the differences in the intermolecular interactions which are functions of their molecular packings (though the molecular structure of course).

If the above story remains valid for C_1 TET-TTF which has the bent but the same C_6S_8 skeleton as the conjugation system, C_1 TET-TTF molecule also should have an ability to form an electrical conductor as far as the grade of TTC_{10} -TTF. C_1 TET-TTF in fact shows the low resistivity almost equal to that of TTC_{10} -TTF (section 2-4). The molecular packing suitable for the electrical conduction must be observed in this C_TET-TTF crystal.

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Crystal Structure

The crystal is monoclinic with space group $P2_1/c$. Figure 2-12 shows the crystal structure projected along the a axis. Eight molecules are contained in the asymmetric unit, and they are piled up along the b axis which is the longest crystallographic one (31.303(6) Å). The resistivity measurements were performed in the direction parallel to the most elongating axis of the crystals which was identified as the crystallographic a axis from X-ray oscillation photographs.

Relatively close intermolecular sulfur to sulfur distances, which are shorter than the upper limit of the sum of the van der Waals radii (3.7 Å), are found only among the molecules I. The molecule II, which is isolated in the crystal judging from atomic contacts, could not directly contribute to the electrical conduction, but it is actually one of the essential components of this conducting crystal.

The molecules are arranged side-by-side regularly along the a axis. Four short $S \cdot S$ distances $(3.49 \vee 3.62 \text{ Å})$ for a molecule I are observed in that direction, and they are kept among one outer sulfur atom and two inner ones (Fig. 2-13). In the direction along the c axis, two close $S \cdot S$ distances (3.60 Å) for a molecule I are observed which are maintained among two inner sulfur atoms (Fig. 2-14).

As a result, the molecules I form the two-dimensional

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sulfur to sulfur networks parallel to the ac plane. The molecules II are sandwiched between those sheets made of molecules I.

It is important to notice that the inner sulfur atoms, which are included in TTF skeleton and are expected to have the largest atomic population of HOMO (section 2-1), greatly participate in the formation of the S \cdot S networks, as shown in Fig. 2-15. In the six contacts for a molecule, the four arise from the inner sulfurs.

Table 2-4. summarizes the manners of S++S networks and the conducting properties of C_1 TET-TTF, TTC₁-TTF (phase 1 and 2), BEDT-TTF, and TTC₁₀-TTF for comparison.

What is common to C_1 TET-TTF and TTC₁₀-TTF (both show the same order of resistivity, 10⁵ Ω cm) seems to be the strong interactions among the conjugation systems. The close S··S networks through inner sulfur atoms look to play an important role in C_1 TET-TTF. The close face to face stacking (3.49 Å) of the C_6S_8 plane with short S··S contact (3.57 Å) of inner sulfur atoms looks to contribute to the conduction in TTC₁₀-TTF.

BEDT-TTF molecules are dimerized in a face to face fashion with 3.69 Å distance between inner sulfur atoms. The dimers are arranged side-by-side regularly to form the dimers of chains along the a axis. In the eight S··S contacts (3.48 \sim 3.69 Å) for a molecule, only three include

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the inner sulfur atoms. Such differences in the quality of S··S networks from C_1 TET-TTF would be responsible for the larger resistivity and activation energy. Nevertheless, the side-by-side regular arrangement of BEDT-TTF shows the resistivity smaller by a factor of three than that of TTC₁-TTF (phase 1).

 ${\rm TTC}_1 - {\rm TTF}$ (phase 1) has a lot of S··S contacts (3.48v 3.66 Å)²⁷⁾ only among the outer sulfurs on which sufficient atomic population could not be expected (section 2-1). What is worse, the molecular planes of the nearest neighbors are almost perpendicular to each other. This situation is quite disadvantageous to the close interactions among the conjugation systems.

The phase 2 of TTC_1 -TTF also has S··S contacts (3.59 Å) only among the outer sulfurs. In contrast to the phase 1, the molecule is flat except for two methyl groups standing nearly perpendicular to the molecular plane. The molecules are stacked regularly, and the overlap pattern of two molecules within a stack is very reminiscent of that of TTC_{10} -TTF. However, the intermolecular separation seems to be larger, judging from that the shortest S··S distance (3.72 Å) between the planes is longer than that for TTC_{10} -TTF (3.57 Å).

From the above comparison with the related molecules, the characteristic feature of the C.TET-TTF crystal is again

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elucidated to be the close intermolecular $S \cdot S$ contacts greatly contributed by the inner sulfur atoms. In addition, the poor flatness of the C_1 TET-TTF molecule would have increased a relative importance of the side-by-side interactions. In order to discuss the intermolecular interactions quantitatively, the intermolecular overlaps in these crystals should be investigated.

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2-6. Donor Abilities of C_TET-TTF in Solution

The redox properties of $C_n TET-TTF$ in solution were investigated by cyclic voltammetry with a polarographic analyzer, Yanaco P-1100 and a X-Y recorder, GRAPHTEC WX2400. The potentials were measured in acetonitrile solutions at room temperature with respect to the saturated calomel electrode (SCE) by use of platinum electrodes as the working and counter electrodes. $n-Bu_4NBF_4$ was used as a supporting electrolyte (0.1 mol/dm³ in acetonitrile).

The resulting values are summarized in Table 2-5 together with those of BEDT-TTF, TTC_1 -TTF, and TTC_7 -TTF measured in the same conditions. The first redox potential (E_{ro}^1) of C_n TET-TTF is independent of n within the experimental error indicating that the molecular ionization potential of C_n TET-TTF in solution is independent of the length of the alkyl chains (Fig. 2-16). The second redox potential (E_{ro}^2) and the difference (ΔE) between E_{ro}^2 and E_{ro}^1 of C_n TET-TTF are also independent of n (Table 2-5).

The redox potentials of $C_n^{\text{TET-TTF}}$ are almost equal to those of BEDT-TTF and $\text{TTC}_n^{\text{-TTF}}$ (Table 2-5). It is already known that $\text{TTC}_n^{\text{TTF}}$ shows constant redox potentials irrespective of n in solution¹¹. These results indicate that the redox properties of the alkylated C_6S_8 electron donor in solution is not influenced by the shape and size of

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the whole molecule. Such understandings would conform to the experimental result²⁸⁾ that the ionization energy of BEDT-TTF and TTC₁-TTF is almost equal to each other in the gas phase, and to the calculated result^{14a)} that the electronic levels of the C_6S_8 core are scarcely influenced by its conformations.

Since the valence electronic states of C_n TET-TTF as one molecule can be regarded as insensible to the change of n, the n dependence of the resistivity in solid state (section 2-4) should come from the difference in the magnitude of interactions between the conjugation systems.

 $\Delta E \text{ is considered to be a measure of the on-site Coulomb repulsive energy for a molecule. The value of <math display="inline">C_n^{} \text{TET-TTF}$ is comparable to that of BEDT-TTF which is known as a good electron donor giving a lot of conductive cation radical salts. Therefore, it is possible that $C_n^{} \text{TET-TTF}$ will give the conductive cation radical salts including superconductors, as far as its electronic property as one molecule is considered.

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2-7. Summary

C_nTET-TTF (n=1, 2, 4, 7, 10, 13, 16, 18) was synthesized by the coupling reaction between the ketones. In spite of the large differences in the molecular shapes from TTC_-TTF, C_TET-TTF shows the n dependence of melting points similar to that of TTC_p-TTF, indicating an arrangement control of the C₆S₈ segments by two alkyl chains for a molecule in solid. This interpretation conforms to the result that the resistivity of C10TET-TTF is smaller by a factor of four than that of C2TET-TTF. C1TET-TTF single crystals showed an extremely low resistivity (5.4 $\times 10^5~\Omega {\rm cm})$ as a single component organic compound. The crystal structure analysis of C, TET-TTF indicates that the C_6S_8 segment is bent in a boat form, and that several close sulfur to sulfur intermolecular contacts are observed in which the inner sulfur atoms greatly contribute to form the two-dimensional networks. The donor ability of C_TET-TTF was measured by cyclic voltammetry. Its redox property in solution was independent of the length of alkyl chains, and almost equal to that of BEDT-TTF.

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Fig. 2-1. Melting points of C_n TET-TTF and related compounds. The mp of C_4 TET-TTF is lower than that (12 °C) of C_7 TET-TTF. BEDT-TTF decomposes at 260 °C¹⁵). The data of TTC_n-TTF were reproduced from ref. 13a).

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Fig. 2-3. Melting $^{69)}$ and boiling $^{68)}$ points of n-alkanes.

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Fig. 2-4. The glass cell for the resistivity measurements.

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Fig. 2-6. Powder X-ray diffraction pattern of $C_{10}TET-TTF$. The numerals represent n in the equasion, 2dsin0 =n λ , where d=38 Å and λ =1.542 Å.

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(a)



Fig. 2-7. (a) The crystal structure of TTC₁₀-TTF projected onto the bc plane⁵⁸; (b) A schematic representation of the packing of C_{10} TET-TTF.

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TTC₁-TTF phase 1







(c)

Fig. 2-11. Molecular side views of TTC_1-TTF (phase 1)^{21a}) (a), TTC_1-TTF (phase 2)^{21b}) (b), and BEDT-TTF²⁶) (c).

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Fig. 2-12. Crystal structure of C₁TET-TTF projected along the a axis. I or II refers to the respective molecule in Figures 2-9 and 2-10.

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Fig. 2-13. The side-by-side arrangements of the molecule I along the a axis. The dotted lines indicate the close sulfur to sulfur distances $(3.49 v_3.62 \text{ \AA})$.

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Fig. 2-14. The molecular arrangements along the c axis. The close sulfur to sulfur distances (3.60 Å) are only found among the molecules I.

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Fig. 2-15. The manner of the sulfur to sulfur interactions for a molecule I.

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Fig. 2-16. The first redox potentials of C_nTET-TTF and the related molecules. Pt vs. SCE in CH₃CN solution, 0.1 mol/dm³ TBABF₄, 100 mV/s.

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Table 2-1. Resistivities of $\textsc{C}_n \textsc{TET-TTF}$ and BEDT-TTF.

n	ρ _{rt} /Ωcm	
1	5.34x10 ⁵	$(E_a = 0.26 \text{ eV})$
	*1.17x10 ⁸	4
2	6.44x10 ⁷	(E_=0.45 eV)
	*4.81x10 ⁹	ŭ
10	*1.01x10 ⁵	
13	*2.26x10 ⁷	
16	*1.83x10 ⁷	
18	*1.85x10 ⁷	
BEDT-TTF	2.60x10 ⁷	(E_=0.44 eV)
	*1.31x10 ⁹	a

*:Compaction pellet

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Table 2-2. Crystallographic data for C₁TET-TTF.

Chemical Formula	C10 ^H 10 ^S 8
F.M.	386.8
Crystal system	monoclinic
Space group	P21/c
a/Å	7.7821(9)
b	31.303(6)
C	13.021(1)
β/°	98.10(1)
v/Å ³	3140.4(7)
Z	8
d _{calcd} /gcm ⁻³	1.63
R	0.049
20 _{max} /°	60
No. of unique data	6676
(F ≧2σ(F))	
Crystal size/mm	0.35×0.35×0.30
(Mo Ka)/cm ⁻¹	10.73
(Mo Kα)/Å	0.71069

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Table 2-3. Atomic coordinates of C1TET-TTF.

NO	ATOM	ATES OF AT	THE CINPUT) AND THEIR	STANDARD DEV	TATIONS				
nu	Alon	-		2	**	BT	CZ	5(X)	S(Y)	S(Z)
1	51	1.04239	0.28496	0.97146	8.11198	8.92010	12.64958	0.001	01 0.0012	5 0.00091
4	32	0.76739	0.30/15	1.09494	5.97190	9.61471	14.25722	0.000	86 0.0012	5 0.00078
3	53	0.76826	0.28439	0.76238	5.97368	8.90226	9.92695	0.001	01 0.0012	5 0.00091
9	24	0.48366	0.30388	0.58097	3.76389	9.51235	11.47111	0.000	93 0.0012	5 0.00091
5	22	1.33195	0.30702	1.13135	10.36537	9.61065	14.75130	0.001	01 0.0015	0 00106
6	56	1.01669	0.32935	1.28289	7.91178	10.30964	16,70451	0.000	93 0.0012	5 0 00092
7	\$7	0.54960	0.29953	0.555552	4.27704	9.37619	7.23343	0.001	09 0.0012	0.00091
8	58	0.22347	0.31557	0.69039	1.73907	9.87829	8.98957	0.000	91 0 0012	5 0 00001
9	59	0.74667	0.43632	0.82449	5.81066	13.65812	10.73568	0.001	09 0 0012	5 0 00104
10	\$10	1.01670	0.48088	0.72771	7,91206	15.05298	9.47551	0 001	01 0 0012	5 0 80001
11	\$11	0.50210	0.43261	0.00126	3.90739	13.56199	7.82901	0 001	01 0 0017	0 88081
12	512	0.77952	0.47511	0.50151	6.06630	14.80976	6 53016	0.000	91 0.0012	0.00091
13	\$13	0.97645	0.41191	1.01440	7.59883	12.49402	13.20150	0.001	12 0.00015	0.00071
14	514	1.29780	0.46591	0.90207	10.09961	16 58618	11 745#5	0 001	17 0 0017	0.00104
15	515	0.27767	0.41714	0.39385	2 16086	13 05773	5 17812	0.001	00 0.0012	0.0011/
16	\$16	0.58409	0.46167	0.28642	4.54545	16 65165	3 72967	0.001	09 0.0012	0.00091
17	C1	0 82286	0.29782	3 97374	6 60162	9 17766	12 26051	0.001	TO 0.0012.	0.00041
18	67	0.70830	0 29708	0.88380	5 51204	9 79949	11 50704	0.003	50 0.0040.	0.00313
19	C3	1.10767	0.10617	1 09700	\$ 62000	9 54336	14 78686	0.003	38 0.0040	0.00313
20	C 4	0.98751	0.51671	1 15755	7 44599	9 251 17	15 00715	0.003	17 0.003/1	0.00513
21	65	0 57033	0 10111	0 60005	6 6 78 76	7.4313/	13.00/33	0.003	11 0.0034	0.00299
22	64	0 44013	0 10896	8 74577	1 62511	9 (7075	0.77220	0.003	58 0.0040	0.00313
23	C7	1 14 201	0 31149	1 27110	10 50910	7.0/0/3	7.70415	0.003	50 0.303/4	0.00313
26	č.	1 20071	0 20267	1	10.39930	9./303/	19.55098	0.003	81 0.0047	0.00434
25	69	0 76701	0 17447	8 52811	7.41424	9.311/3	17.20242	0.004	12 0.0043	0.00365
26	C10	0 14110	8 14777	0 764 59	1 75625	10.22418	4.88789	0,005	37 0.0065	0.00469
27	C11	0.11767		0.70017	1.43373	11.33462	9.83139	0.004	90 0.00471	0.00482
	6117	0.01292	0.43610	0./074/		19.2/91/	9.24322	0.003	50 0.0040	0.00332
20	614	0.71273	0.43366	0.01031	2.34623	14.20780	8.0249/	0.003	42 0.0037	0.00339
10	614	1 070/23		0.07421	1.44728	13.89819	11.64351	0.003	74 0.0040	0.00326
30		1.0/758	0. 43/ 1/	0.65106	8.90218	14.31383	11.08165	0.003	50 0.0037	0.00326
34	CIA	0. 107770	0.4334/	0.48337	3.56622	13.03151	6.03958	0.003	50 0.0037	6 0.00326
11	617	1 17714	0.43311	0.42027	4.64693	14.183/0	5.4/242	0.003	58 0.0037	0.00326
22	611	1.1/217		1.0/010	7.121/1	13.68160	14.03899	0.006	54 0.0072	0.00482
17	610	1.31367	0.430/0	1.022/3	10.54034	13./2430	13.31/23	0.006	77 0.00876	0.00625
33	670	0.13039	0.39940	0.49231	1.21860	12.50241	6.41037	0,004	20 0.0050	0.00430
20	47.	0./1106	0.41606	0.24691	3.33334	13.08653	3.29106	0.006	07 0.0059	5 0.00495
34	47.8	1.40130	0.27412	1.23722	11.3/329	9.20778	16.78695	0.000	00 0.0000	0.00030
20	1/8	1.37432	0.34110	1.27443	10.83229	10.0//45	10.85503	0.000	00 0.00001	0.00000
37	nea	1.10303	9.25470	1.30820	9.0/103	8.29901	17.03406	0.000	00 0.0000	0.00000
40	165	1.23663	0.29962	1.38446	9.62374	9.37900	18.09213	0.000	00 0.00001	0.60630
74	074	0.83800	0.30925	0.336/9	0.50584	9.68159	7.24996	0.000	00 0.00000	0.00000
26	778	0.72203	0.32229	0.44694	5.61891	10.08864	5.81960	0.000	00 0.00001	0.00000
	HAC	0.75815	0.35207	0.55983	5.90000	11.02084	7.28955	0.000	00 0.00001	0.00000
	MIGA	0.1625/	0.30037	0.82376	1.26514	11.28692	10.72618	0.000	00 0.00001	0.00000
45	H108	0.04234	0.36402	0.73057	0.32949	11.39491	9.51275	0.000	00 0.00001	0.00000
46	HIOC	0.22736	0.38601	0.74941	1.76934	12.08327	9.75807	0.000	00 0.00001	0.00000
4/	HIZA	1.19659	0.41999	1.13595	9.31199	13.14694	14.79121	0.000	00 0.00001	0.00000
. 98	H175	1.12914	0.47350	1.07468	8.78708	14.82197	13.99541	0.000	00 0,00001	0,00000
49	HISA	1.31290	0.40307	1.00679	10.21712	12.61730	13.10941	0.000	00 0.00001	0.00000
50	H185	1.43299	0.44200	1.05269	11.15167	13.83592	13.70707	0.000	00 0.0000	0.00000
51	H19A	0.21882	0.37846	0.53581	1.70288	11.84695	6.97678	0.000	00 0.00001	0.00000
52	H195	0.05049	0.38896	0.45959	0.39292	12,17561	5.98432	0.000	00 0.00000	0.00000
53	H19C	0.12961	0.41938	0.53810	1.00364	13,12785	7.00669	0.000	00 0.00001	0.00000
54	HZCA	0.67535	0.38995	0.27631	5.25564	12 20660	3.59781	0.000	00 0.00001	0.00000
55	HZOB	0.70628	0.41091	0.18125	5.49634	12.86271	2.36005	0.000	00 0.0000	9.00000
56	HZOC	0.82092	0.41749	0.28629	6.38845	13.06869	3.72778	0 000	00 0 0000	0 00000
								0,000		

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side-by-side	3.49~3.62 Å	
P//a=5.4×10 ⁵	Ω cm (E _a =0.26	eV)



interplane 3.49 Å (S··S 3.57 Å)⁵⁸) $\rho_{//stack}$ =3.7×10⁵ Ωcm (E_a=0.13 eV)¹²)

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Table 2-4. (continued)

BEDT-TTF







 $P_{//a} = 2.60 \times 10^7 \ \Omega \text{cm} \ (E_a = 0.44 \ \text{eV})^*)$

S.S 3.4823.69 Å26)

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Table 2-4. (continued)

TTC₁-TTF (phase 1)



S··S 3.48 $^{3.66}$ Å^{21a)} $p=2.9\times10^{10}$ Ω cm (E_a=0.38 eV)¹²⁾

TTC₁-TTF (phase 2)^{21b})





nearly flat molecular plane

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Table 2-5. Redox potentials (V) of C_nTET-TTF and the related molecules. Pt vs. SCE in CH₂CN solution.

Pt vs. SCE in CH₃CN solution, 0.1 mol/dm³ TBABF₄, 100 mV/s.

	C_TH				
n	Ero	E ² ro	ΔE		
1	0.52	0.76	0.24		
2	0.53	0.79	0.26		
4	0.53	0.77	0.24		
7	0.54	0.78	0.24		
10	0.53	0.78	0.24		
13	0.54	0.78	0.25		
16	0.54	0.78	0.24		
18	0.53	0.79	0.26		
BEDT-TTF	0.53	0.77	0.24		
TTC1-TTF	0.54	0.77	0.23		
TTC7-TTF	0.55	0.79	0.24		

$$\Delta E = E_{ro}^2 - E_{ro}^1$$

The redox potential of ferrocene in the same condition was 0.44 V.

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Table 2-6. Yields (%) and melting points of C TET-TTF.

n	db	m.p./°C
1	62	80.2-81.2
2	75	79.0-80.0
4	51	
7	58	11.4-13.4
10	70	40.5-41.0
13	37	61.0-62.0
16	52	73.0-74.0
18	43	76.5-77.5

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LDA: lithium diisopropylamide

Scheme 2-1. Synthetic routes to $C_1 TET-TTF$, (a)²⁹⁾ and (b)¹⁹⁾.

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R=CnH2n+1





Scheme 2-2. Synthetic scheme of C_n TET-TTF.

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 $O = (R = C_n H_{2n+1})$ n=4,7,10,13,16,18





Scheme 2-3. Synthetic scheme of the ketones.

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3. Preparation, Crystal Structures and Properties of Cation Radical Salts of ${\rm C_nTET}\text{-}{\rm TTF}$

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3-1. Introduction

Among the C_6S_8 compounds in Fig. 1-1, BEDT-TTF has attracted the most attention because it has given a lot of metallic cation radical salts including superconductors. Its charge transfer (CT) complexes with organic acceptors have also been reported,¹⁾, ³⁵⁾, ³⁶⁾ but, the studies on single crystalline samples have been known only about (BEDT-TTF)(TCNQ).³⁶⁾ Contrary to the cation radical salts, a metallic conduction in BEDT-TTF CT complex has been observed only on the triclinic phase of (BEDT-TTF)(TCNQ) around room temperature.^{36a)}

 $\rm TTC_1-TTF$ has given more single crystalline CT complexes than BEDT-TTF has, probably due to its larger solubility in organic solvents. The single crystalline cation radical salts with inorganic anions have also been reported though they are inferior to those of BEDT-TTF in their kinds and numbers. $\rm TTC_1-TTF$ tends to give 1:1 salts with monovalent anions. As mentioned in section 1-2, $(\rm TTC_1-TTF)I_{2.47}$ is the only example in all.TTC₁-TTF CT and radical complexes that shows the metallic temperature dependence of resistivity, so far.

Compared with the above two donors, TTC_n -TTF (n22) has scarcely been reported as a component of cation radical salts or CT complexes. A powder complex with the

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composition of TTC_7 -TTF:Br=1:6 was obtained by a direct mixing of TTC_7 -TTF and bromine in hexane solution.¹⁵⁾ No other example of TTC_n -TTF (n22) complex with inorganic species is available in the literature. As for the CT complexes, TCNQ^{37}), $\text{F}_4\text{TCNQ}^{15}$, hexacyano-1,3-butadiene¹⁵) (HCBD), 2,3-dibromo-5,6-dicyano-p-benzoquinone¹⁵) (DBDQ), and 9-dicyanomethylene-2,4,5,7-tetranitrofluorene²⁷⁾ (DTENF) were reported as acceptors. In the system of (TXC_n -TTF)(TCNQ) (X=S, Se, Te; n=2, 3), the structure analyses showed that the donor and acceptor molecules were alternately stacked in their crystals.³⁷) Imaeda et al. described that TXC_n -TTF (n≥4) did not form the CT complexes with TCNQ.³⁷)

According to our results,¹⁵) TTC₇-TTF has more difficulty in forming CT complexes than C₇TET-TTF does. F₄TCNQ, HCBD, and DBDQ, which are all stronger acceptors than TCNQ gave the complexes as solid with the both donors. TCNQ and more weaker acceptor, dimethyl TCNQ (DMTCNQ) formed the CT complexes with C₇TET-TTF but not with TTC₇-TTF. Although C₇TET-TTF has the alkyl chains only on its one side of the molecule, an aligning effect by the alkyl chains are recognized through the single crystal structure analyses¹⁵), ³⁸ on the neutral complexes, (C₇TET-TTF)(TCNQ) and (C₇TET-TTF)₂(DMTCNQ). It is desired to develop the cation radical slats of C₇TET-TTF, because the intrinsic character of the

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unsymmetrical donor would be more clearly exhibited and more conductive substances would be expected than in its CT complexes, and because the arrangement of the radical part would be controlled by the alkyl chains which are directly attached to it.

Some related compounds to ours¹⁵ possessing the long alkyl chains have been reported in connection with the formation of Langmuir-Blodgett films; $C_n \text{TET-TTF}$ (n=12 and 18)³¹, an unsymmetrical $\text{TTC}_n - \text{TTF}^{39}$, and BEDT-TTFC_n (n=16, 18, and 20)⁴⁰.

The attempts to get the BEDT-TTF cation radical salts containing anionic surfactants as counter anions have been made but not succeeded. 15, 41)

Some of the complexes of C_1 TET-TTF have appeared in the literature (TCNQ,²⁹⁾ I_3 ,¹⁹⁾, ³⁴⁾ and $IBr_2^{19)}$, but the structures and physical properties of single crystals have not been described.

In this chapter, the cation radical salts of C_n TET-TTF are discussed especially on preparation, crystal structures, and conducting properties of C_1 TET-TTF salts. An attention is also focused on $(C_1$ TET-TTF)_4Sb_2F_11 which may result from the in situ generation of Sb_2F_11 anion in the electrochemical process.

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3-2. Preparation of Cation Radical Salts of C_TET-TTF.

Since $C_n^{TET-TTF}$ shows the same redox properties as BEDT-TTF does in solution (section 2-6), we have tried preparing its cation radical salts by a conventional electrochemical method. The electron donor $C_n^{TET-TTF}$ (n=1, 2, 7, 13), and a supporting electrolyte n-Bu₄NX (X=PF₆, AsF₆, SbF₆, BF₄, ClO₄, ReO₄, I₃, IBr₂, AuI₂, AuBr₂, Au(CN)₂, Br₃, Br, I, CuSCN+KSCN+18-crown-6 ether, etc.) were dissolved in organic solvent (methanol, ethanol, acetonitrile, n-hexane, benzene, dichloromethane, etc.), and the electrolysis was carried out at a constant current (ca. 1 µA). A two-compartment H type glass cell and platinum electrodes were used (Fig. 3-1).

A typical procedure for the PF_6 salt of C_1 TET-TTF was as follows. 5.6 mg of C_1 TET-TTF (14.5 mmol) and 43.6 mg of TEAPF₆ (113 mmol) were place separately in the each compartment of the cell with Teflon coated stirring cores and the atmosphere in the cell was exchanged several times by argon gas. 18 cm³ of dry methanol (distilled over magnesium methoxide) was added and the mixture was stirred under argon overnight. After the stirring cores were removed, the platinum rod electrodes of 1 mm in diameter and 4 cm long (burned just before the use) were immersed into both compartments through Teflon holders. The electrolysis

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was carried out at a constant current of 1 $_{\rm \mu A}$ at room temperature in the dark for 44 h. Black elongated plates were obtained, washed with methanol and dried under reduced pressure.

Up to now, the products have been obtained only from C_1 TET-TTF and C_2 TET-TTF. For n=7 or 13, the color of the solution changed from orange to dark brown as the current flowed, suggesting the formation of the cation radical of the donor. Any solid product was not crystallized, even when the electrolysis was carried out at ca. 5 °C for n=7. The reason why C_n TET-TTF of large n has difficulty in giving the salts may come from its long alkyl chains. The oxidation of the C_6S_8 segment may possibly influence the conformations of the alkylthio groups to restrict the directions of the alkyl chains. Further conditions of the solvents or temperature should be examined any way.

Table 3-1. summarizes the conducting properties of the cation radical salts of C_1 TET-TTF and C_2 TET-TTF obtained so far. Among them, those which show the metallic temperature dependence of resistivity will be described in sections 3-3 and 3-4.

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3-3. (C1TET-TTF)2~X (X=PF6 and AsF6)

3-3-1. Crystal Structures

We have determined the crystal structures of four kinds of C_1 TET-TTF cation radical salts with respect to the anions (PF₆ or AsF₆) and solvents (methanol or ethanol) used.

X-Ray diffraction data for structure analyses of the PF_c salts of C₁TET-TTF were collected at ambient temperature by an automated four-circle diffractometer, Enraf-Nonius CAD4, with graphite-monochromated Mo K α_1 radiation (λ =0.70930 Å), using the $2\theta-\omega$ scan technique. Crystal structures were solved by a direct method using MULTAN82 program. A total of 3996 reflections were measured (2°≤20≤ 55°) and 2053 reflections with $|F_0| \ge 2.5\sigma(|F_0|)$ were observed and 1962 independent ones were used for the analysis of the PF6 salt grown in the methanol solution. A total of 4021 reflections were measured (2°≤28≤55°) and 2072 reflections with $|F_{a}| \ge 3.0\sigma(|F_{a}|)$ were observed and 1987 independent ones were used for the analysis of the PF₆ salt grown in the ethanol solution. Non-hydrogen atoms were refined anisotropically including the occupancy of the anion using a full-matrix least-squares method. The final atomic parameters of the PF5 salt grown in methanol and those of

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the PF_6 salt grown in ethanol are listed in Tables 3-2 and 3-3, respectively.

X-Ray diffraction data for structure analyses of the AsF₆ salts of C₁TET-TTF were collected at room temperature by an automated four-circle diffractometer, Rigaku AFC-5, with graphite-monochromated Mo Kα radiation (λ =0.71069 Å), using the 20- ω scan technique. Crystal structures were solved by a direct method using MULTAN program. The structure of the AsF₆ salt of C₁TET-TTF grown in ethanol was refined anisotropically including the occupancy of the anion using 3018 independent reflections by a full-matrix least-squares method (RADIEL program).

Crystallographic data of the four crystals of C₁TET-TTF salts used for structure determination are summarized in Table 3-4. Only one crystallographically independent donor molecule is observed in each crystal.

The four PF_6 and AsF_6 crystals are isomorphic with slight differences in the anion arrangement (vide infra). The crystal structure of the PF_6 salt grown in methanol is shown in Fig. 3-2 as a representative. The donor molecules stack uniformly along the c axis which is the elongated direction of the crystal. The distance between the C_6S_3 planes in the column is 3.59 Å for the PF_6 salts, and 3.58 Å for the AsF_6 salts. No intermolecular sulfur to sulfur distance shorter than the sum of the van der Waals radii

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 $(3.6 \sim 3.7 \text{ \AA})$ is observed within a column. The side view of a stacking column is shown in Fig. 3-3a. The mode of overlapping of the molecules within the column is shown in Fig. 3-3b. The molecules look to be slid diagonally each other so as to keep away from the methyl carbons possessing the large thermal motions.

On the other hand, some short S··S distances are found in the side-by-side direction (3.54 3 .68 Å for the PF₆ salts, and 3.54 3 .69 Å for the AsF₆ salts), and the donor molecules are slightly dimerized in that direction (Figures 3-4 and 3-5). These results present a contrast to those of β -(BEDT-TTF)₂PF₆⁴²) which has uniform and shorter side-byside S··S contacts (3.44 3 .52 Å) and a tetrameric repeating unit in a column.

The projection along the long molecular axis is shown in Fig. 3-6. The regular spacing between the molecular planes and the short sulfur to sulfur distances in the sideby-side direction suggest a two-dimensional intermolecular interactions in the ac plane.

As shown in Figures 3-4 and 3-5, slight differences between the PF₆ salts and the AsF₆ salts are observed in the pattern of S··S contacts, though the mode of the shortest distances (3.54 Å) is common to each other. In the PF₆ salts, the short distances are observed only among the sulfur atoms of ethylenedithic groups and TTF skeletons

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(Fig. 3-4). In the AsF_6 salts, one of the two sulfur atoms of the methylthio groups participates in the S··S networks (Fig. 3-5).

It is noteworthy that the asymmetric donor molecules are all oriented in the same direction within a column. It is hard to find such examples in the complexes of asymmetric TTF skeleton analogues except for (trimethylene-TTF)(TCNQ),⁴³) and (MDT-TTF)₂Au(CN)₂.⁴⁴) In the conventional complexes of noncentrosymmetric TTF analogues, the donor molecules stack alternately in head-to-tail manner within a column.⁴⁵, 46)

The interactions between hydrogen atoms and fluorine atoms are not recognized judging from the interatomic distances between the carbon atoms of the alkyl groups and the fluorine atoms.

The molecular structure of $C_1 \text{TET-TTF}$ in $(C_1 \text{TET-} \text{TTF})_2(\text{AsF}_6)_{0.79}$ with bond lengths is shown in Fig. 3-7 as a representative. The bendings of the C_6S_8 segment are decreased compared with the neutral molecules (Fig. 2-10). The ethylene group and the methyl groups are placed in the opposite side with respect to the molecular plane (Fig. 3-7b). The thermal motions of the ethylene carbons are large, indicating the conformational disorder. One of the methyl carbons are also disordered since it is observed in the two

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positions. In the cation radical salts with partial charge transfer, the substitution of one ethylenedithio group of BEDT-TTF by two methylthio groups might cause the increase in freedom of the outer alkyl groups keeping the C_6S_8 core flat and rigid.

The bond lengths of the TTF skeletons in these cation radical salts are summarized in Table 3-5 together with those in the neutral $C_1TET-TTF$. According to the investigations on BEDT-TTF salts⁴⁷⁾ and TTC_1 -TTF salts^{21a)}, ⁴⁸⁾, the bond lengths of the TTF segment are sensitive to the change of the oxidation states of the molecule. However, any systematic correlation between the bond lengths and the formal charge of $C_1TET-TTF$ can not be deduced from our result at present. The reason is not clear, and the other salts of $C_1TET-TTF$ including those of 1:1 stoichiometry should be studied further.

Somewhat complicated anion arrangements were observed. In the PF_6 and AsF_6 salts grown in methanol, the anions are positionally disordered at two sites 0,0,1/2 and 0,0,0 with occupancies of 0.64 and 0.21 for the PF_6 salt, 0.61 and 0.18 for the AsF_6 salt, respectively. Thus the (D:X) of these salts are 2:0.85 and 2:0.79, respectively (see Table 3-4). Similar anion deficiencies were commonly recognized in other two salts grown in ethanol by structure refinements, and

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were in some cases confirmed by elemental analyses and specific gravity measurements. In the salts grown in ethanol, the anion occupies 0,0,1/2 and shows no positional disorder. The occupancies of the anions are summarized in Table 3-6. One of the reasons for the deficiency and disorder of the anion would be the weak interaction between the anion and the alkyl groups of the donor (vide supra).

Satellite reflections with indices $l=n\pm 1/5$ (n:integer) were clearly observed in oscillation photographs around the c axis at room temperature in the case of the PF₆ salt grown in methanol. These reflections indicate a fivefold modulation of the structure along the c axis. Similar superstructures were commonly observed in other three salts as temperature decreased. Such modulation would come from the anion deficiencies, the conformational disorders of the alkyl groups, and the positional disorders of the anions.

In our preliminary MS measurements on these salts grown in methanol or ethanol, a peak at m/e=32 or 46 was observed, respectively. The PF₆ salt grown in isopropanol gave a peak at m/e=60. Although it is possible to consider the incorporation of the solvent into the crystal accompanied by the anion deficiency, further investigations should be carried out to distinguish those peaks from many fragment peaks of C₁TET-TTF coexisting in such a low mass number region.

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3-3-2. Conducting and EPR Properties

Electrical resistivity along the long axis of these crystals was measured by the standard d.c. four-probe method using 10 µm-diameter gold wires with gold paste (Tokuriki 8560) as electrical contacts, between room temperature and 1.5 K.

Electron paramagnetic resonance (EPR) spectra were recorded on an X-band spectrometer, JEOL JES-FEIXG with a cylindrical cavity (TE_{011}), equipped with a helium-flow cryostat, Air Products LTR-3-110. The single crystal was mounted on a quartz capillary with silicone grease, then sealed into a quartz sample tube with 10 mmHg pressure of helium gas. The temperature dependence of EPR spectra was measured for the static magnetic field normal to the long axis of the crystal and the g-factor maximum at room temperature. $Li^{+}TCNQ^{-}$ (g=2.0026) was used as a standard sample of g-factor. In some cases, the temperature dependence of the resistivity was measured for the same crystal that had been used for the EPR experiments after silicone grease was washed away with n-hexane.

The temperature dependence of common logarithm of conductivity for the four kinds of the C_1 TET-TTF salts is shown in Fig 3-8. The data shown in Fig. 3-8 were obtained from the same crystals used for the EPR experiment (vide

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infra). The room temperature conductivity was 10×100 S/cm for each salt irrespective of the anion and solvent used (Fig. 3-8). In each case, the conductivity increased monotonically with decreasing temperature down to 150×240 K. Such a metallic behavior is consistent with the crystal structures which indicate both the uniform overlap of the donor molecules along the stacking column and the partial charge transfer. Below the temperature at which the conductivity showed a maximum, the salts exhibited a semiconducting behavior. However, they did not obey the Arrhenius type activated manner in that low temperature region, indicating the invalidity of a simple semiconducting picture for these salts. At least 0.1 S/cm of conductivity was maintained in every case, even at 4.2 K.

For the PF_6 salts, somewhat temperature independent conductivity was often observed regardless of whether the solvent was methanol or ethanol (e.g. the PF_6 salt from methanol in Fig. 3-8). Since any other crystal modifications of these salts have not been detected at present, delicate differences in the degree of disorder seem to affect the transport properties in these crystals.

The anisotropy of the resistivity at room temperature in the largest crystal face of the PF_6 salt grown in methanol was about $\rho_{//c}$: $\rho_{\pm c}$ =1:10. This observation supports the two-dimensional intermolecular interactions that the

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crystal structure of this salt expects.

Figure 3-9 shows the angular dependence of g-factors and peak-to-peak linewidths (Δ H) for these crystals at room temperature. The crystals were rotated around the c axis. Only one Lorentzian signal was observed in the field range between 0 and 6500 G at room temperature for each crystal.

The angular dependence of g-factor for each crystal nearly coincides. This result suggests the nearly identical packings of the C_6S_8 cores in these crystals, as are already indicated by the X-ray structure determinations. The maximum (2.011) and minimum (2.005) g-factors were obtained when the static field was applied nearly parallel and normal to the a^{*} axis, respectively, and these values are comparable with the g-factors of BEDT-TTF cation radical salts.⁵⁶⁾ Almost temperature independent g-factors were observed for each salts.

The salts grown in ethanol gave smaller linewidths than those grown in methanol (25 G vs. 28 G for PF_6 , 22 G vs. 27 G for AsF_6 salts) at room temperature. This means that the relaxation of spins is faster in the salts obtained in methanol than in ones obtained in ethanol, and is consistent with the crystal structures which display the positional disorder of the anion only in the salts grown in methanol. A similar difference in linewidth related to the structural

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disorder was reported for β -(BEDT-TTF)₂I₃.⁵⁷⁾

Figure 3-10 shows relative intensity of EPR signal as a function of temperature for the four salts. These data had been collected before the data in Fig. 3-8 were obtained from the same crystals. In contrast to the somewhat various behaviors of conductivity (Fig. 3-8), normalized EPR intensity showed a common feature regardless of the anion or the solvent used (Fig. 3-10). It would be possible that the "contactless" measurement like EPR may be suited to extract the intrinsic properties of a crystal. In every case, the intensity gradually decreased bellow 200 K, and showed a minimum at around 50%60 K, then it increased at the lower temperature to reach the magnitude comparable to the room temperature value. No sudden decrease in the EPR intensity is observed in Fig. 3-10. The conductivity also decreases gently, as mentioned above. These situations rule out the existence of the phase transition at which the carriers disappear suddenly, in the investigated temperature range. The absolute magnitude of the spin susceptibility for the PF_6 salts was estimated to be about 4×10^{-4} emu/mol at 293 K.

Similar temperature-dependent spin susceptibility has been found in several organic "metals", for example, TTF-TCNQ⁵⁹), TTF-I_x⁶⁰), (TTT)₂-I_{3+ô}⁶¹), (TMTTF)₂x⁶²), and (TMTSF)₂x⁶³). For those guasi-one-dimensional materials, it

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has been considered that a pseudogap based on the onedimensional fluctuation above the Peierls transition temperature can depress the density of states near the Fermi surface even in the metallic state.⁶⁴⁾

The Peierls pseudogap is unsuitable for the mechanism of the thermal variation of the susceptibility of the PF_6 and AsF_6 salts of C_1 TET-TTF, because they are considered to be more two-dimensional on account of the structural and conducting properties mentioned previously. Another candidate to explain Fig. 3-10 above 50 K would be a mixture between the dimer model⁶⁵⁾ and the Bonner-Fisher model⁶⁶⁾, namely, the alternating antiferromagnetic chain model⁶⁷⁾, but it is fundamentally for one-dimensional localized spins.

It is fruitful to remember that the PF_6 and AsF_6 salts of $C_1TET-TTF$ exhibit the anion deficiency and the fivefold modulation of the structure along the stacking column (section 3-3-1). If the averaged stoichiometry is $(C_1TET-TTF)_2(X)_{0.8}$ (X= PF_6 or AsF_6), these salts should have a fifth-filled band. In this band filling, the fivefold periodic distortion of the lattice must produce a gap on a certain position of the Fermi surface, whether the Coulomb repulsion is strong or not. The gap formation like this will lead to a decrease in the density of states near the Fermi level as a whole, but will not mean the complete disappearance of the Fermi surface because these salts are

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not one-dimensional. In fact, the PF_6 salt grown in methanol shows both a metallic conducting behavior and the fivefold satellite reflections simultaneously at around room temperature. The temperature-dependent spin susceptibility for these C_1 TET-TTF salts above 50 K should come from the anisotropic fivefold modulation which would grow stronger at lower temperature.

The increase in the spin susceptibility below 50 K looks like a result of the superimposition of the Curie-like contribution on the conduction carrier paramagnetism, considering the moderate conductivity of these salts at 4.2 K. In order to estimate the concentration of the isolated spins at 4.2 K, we subtracted the conduction spin contribution from the measured susceptibility assuming the carrier concentration of the isolated spins at 4.2 K for the pr₆ salt grown in methanol was estimated to be 10^{-3} spins/molecule. This result means that a spin is isolated on every thousand molecules on an average at the low temperature. The structural modulation along the molecular column and the complicated disorder must give such a concentration of the defects.

A random potential produced by the large magnitude of disorder in these C_1 TET-TTF salts as well as a two dimensionality would be the reason why these salts do not

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3-4. (C1TET-TTF)∿X (X=I3 or AuI2)

The title salts were prepared by an electrochemical method essentially in the same way as described in section 3-3, except that TBAI_3 or TBAAuI_2 was used as a supporting electrolyte and acetonitrile as a solvent. Black hexagonal rods with luster from the I_3 anion, and black rhombic rods from the AuI, were obtained.

As for the crystals from I₃, X-ray photographs showed the presence of a superlattice structure characteristic of iodine complexes.⁴⁹⁾ The structure determination of this salt has not succeeded, because the disorder exists at least in the two directions which is confirmed by oscillation and Weissenberg photographs along the crystal needle axis. The lattice constants were determined using a four-circle diffractometer (30 reflections, 30°520540°, MoKa): a=11.60(1), b=22.62(3), c=9.65(4) Å, α =90.8(3), β =97.2(3), γ =89.7(1)°, and V=2512(11) Å³. The ratio of the donor (D) to the anion regarded as I₃⁻ was estimated to be D:I₃=1: ~0.8 by EPMA. These results reminiscent of (TTC₁-TTF)I_{2.47} in which the iodine lattice composed of I₃⁻ columns is incommensurate with the donor lattice.¹⁰

The salt from AuI_2 gave the similar complicated oscillation photographs along the crystal needle axis. The ratio, D:AuI₂, was also estimated to be 1:0.8 by EPMA.

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The two salts are referred to the ${\rm I}_3$ salt and the ${\rm AuI}_2$ salt, respectively for convenience.

Electrical resistivity and EPR spectra for the single crystals were measured essentially in the same way as described in section 3-3.

Figure 3-11 shows the temperature dependence of common logarithm of conductivity for the two salts. A metal to semiconductor transition was observed in the I_3 salt at 100 K, on the other hand, the AuI₂ salt showed a broad maximum of conductivity at around 250 K. The Arrhenius plots gave the activation energy, $E_a=0.06$ eV for the I_3 salt below 80 K, and $E_a=0.05$ eV for the AuI₂ salt below 130 K.

The EPR intensity of the I_3 salt starts to decrease from rather higher temperature than its transition in conductivity (Fig. 3-12a). The intensity is already decreased at 100 K to 30% of the room temperature value. Below 80 K, the signal behaves in an activated manner with $E_s=0.03$ eV.

The AuI₂ salt shows a somewhat constant intensity down to 220 K (Fig. 3-12b). The ln(IT) vs. T^{-1} plots shows a linear relation giving E_a =0.032 eV between 220 and 150 K (Fig 3-12c). Below 150 K, the data start to deviate from the line probably due to the Curie-like contribution.

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3-5. (C1TET-TTF)4Sb2F11

3-5-1. Preparation and Properties

The sample was electrochemically prepared with a constant current of 0.8 $\mu\text{A/cm}^2$ in dry methanol solution of C₁TET-TTF (1 mmol/dm³) and TBASbF₆ (8 mmol/dm³). In one or two weeks, black hexagonal rods (decomp.=195 °C) grew on the platinum anode.

The ratio of sulfur to antimony in this compound was estimated to be 16:1 by EPMA. The elemental analysis (found: C, 24.20; H, 2.14; N, 0; F, 10.20%) indicates that the composition of this product is $(C_1 \text{TET-TTF})_4 \text{Sb}_2 F_{11}$ (calcd: C, 24.03; H,2.02; F, 10.45%) and not $(C_1 \text{TET-TTF})_2 \text{Sb}_{F_6}$ (calcd: C, 23.80; H, 2.00; F, 11.30%). As shown in 3-5-2, the structure determination exhibits that this product contains a binuclear anion of two antimony centered octahedra sharing a fluorine atom. In the IR spectra of this salt dispersed in a KBr pellet, the sharp and strong absorption was found at 640.4 cm⁻¹ which was ascribed to the Sb-F stratching mode in comparison with NF₄Sb₂F₁₁^{50a)} and TBASbF₆. The absorption at 474.1 cm⁻¹ was also observed but could not necessarily be assigned to the bending mode of the Sb-F-Sb bridge (480~497 cm⁻¹)⁵⁰) because the absorption

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ascribed to C, TET-TTF was superimposed on that region.

In spite of the use of TBASbF₆ (its composition was confirmed by elemental analysis) as a supporting electrolyte, the electrochemical oxidation of C₁TET-TTF in methanol actually gave (C₁TET-TTF)₄Sb₂F₁₁ anyway. Usually, the Sb₂F₁₁ anion is prepared in a strong acidic condition (e.g. CsF+2SbF₅+CsSb₂F₁₁, in SO₂⁵¹⁾). In our case, the Sb₂F₁₁ anion would be generated during the electrolysis and incorporated into the crystal, though the mechanisms are not clear at present. Similar unexpected in situ incorporation of fluorinated anions were recently observed in (TMTSF)₃Ta₂F₁₁⁵²) and probably in (EOET-TTF)₂SbF_x⁵³).

The absorption spectra of $(C_1 \text{TET-TTF})_4 \text{Sb}_2 \text{F}_{11}$ dispersed in a KBr pellet are shown in Fig. 3-13. The absorption was found at 4×10³ and 11×10³ cm⁻¹. The 4×10³ cm⁻¹ absorption could be ascribed to the CT transition between $C_1 \text{TET-TTF}^{\ddagger}$ s or that between $C_1 \text{TET-TTF}^{\ddagger}$ and $C_1 \text{TET-TTF}^{0}$. Since the 11×10³ cm⁻¹ absorption, which could be ascribed to one of the intramolecular transitions of $C_1 \text{TET-TTF}^{\ddagger}$, somewhat broadens, another CT transition may superimpose on it.

The single crystal of this salt showed the conductivity of $\sigma_{\rm rt}=0.4$ S/cm and the semiconducting behavior, $\rm E_a=0.16~eV$ (Fig. 3-14).

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3-5-2. Crystal Structure

X-Ray diffraction data for structure analysis of $(C_1 \text{TET-TTF})_4 \text{Sb}_2 F_{11}$ were collected by an automated fourcircle diffractometer, Rigaku AFC-5, with a graphite monochromated MoKa radiation, using the 20- ω scan technique. A total of 10125 reflections were measured (3°\$20\$60°) and 6774 independent reflections were used for the analysis. The structure was solved by a direct method, and nonhydrogen atoms were refined anisotropically using a blockdiagonal least-squares method. Crystallographic data are listed in Table 3-7, and the final atomic parameters are listed in Table 3-8, and F_0 - F_c are listed in Table 3-10.

A noncentrosymmetric space group, P1 has been adopted for this crystal. The reduction in the symmetry of the model from P1 to P1 gave a ten percent decrease in the Rvalue (0.069+0.062), and gave the Sb-F-Sb bridging angle of 155° which was consistent with the known value (vide infra). No satellite reflection was observed in oscillation and Weissenberg photographs at room temperature.

Crystallographically independent four donor molecules and one ${\rm Sb}_2{\rm F}_{11}$ anion are contained in the unit cell (Fig. 3-15). The molecular structures of the donor are shown in Fig. 3-16 together with the numbering of atoms. No systematic difference was recognized in the bond lengths of

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the four donor molecules. The thermal motions of the alkyl groups are relatively small (Table 3-9), and the strong interactions between the anion and the alkyl groups are observed (vide infra). This situation is in striking contrast to the $\rm PF_6$ and $\rm AsF_6$ salts in which the anion is also disordered. Such an interaction between the anion and alkyl groups must have a delicate effect upon the structure and physical properties of the salts.

The donor molecules stack almost in parallel to each other along the c axis which is the elongated direction of the crystal. The donors are oriented in the same direction within a stacking column (Fig. 3-17), similarly to the PF_6 and AsF_6 salts. A relatively short sulfur to sulfur distance (3.61 Å) was observed within the column to produce two kinds of overlaps in each column. The dimerization in a column is not serious, and the averaged distance between the $\mathrm{C}_6\mathrm{S}_8$ planes is 3.52 Å which is rather shorter than that of the PF_6 or AsF_6 salt (3.58 \sim 3.59 Å).

In the transverse direction, the donors are seriously dimerized (Fig 3-18). The intermolecular sulfur to sulfur distances within the dimer are 3.38×3.60 Å, and those between the dimers are 3.67×3.70 Å.

The ${\rm Sb}_2{\rm F}_{11}$ anion looks to assist the dimerization of the donors. The relatively short distances between the alkyl groups and the fluorine atom of the anion are observed

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judging from vdW radii (Fig. 3-19). An extremely short C· \cdot F distance of 3.02 Å which is comparable to the sum of the vdW radii of carbon and fluorine (3.05 Å) suggests a hydrogen bond-like interaction.

The structure of the Sb₂F₁₁ anion is shown in Fig. 3-20 together with the bond lengths. The coordination of Sb by F is octahedral with slight distortion. The averaged Sb-F length for each octahedron is 1.84 and 1.86 Å, as is usual⁵⁴⁾. The bridging Sb-F-Sb angle is 154.88(99)° in accord with the conventional value of 150~160°⁵⁵⁾ for the angle at the μ -F atom of the Sb₂F₁₁⁻ ion. Although the direct estimation of the valence of Sb in (C₁TET-TTF)₄Sb₂F₁₁ by ESCA was unsuccessful because of the decomposition of the sample, we could be able to regard the charge of Sb₂F₁₁ in this salt as -1 on the basis of the structural data.

If no charge separation exists among the donor molecules, the charge of the one donor is +0.25 meaning a partial charge transfer. However, this salt is a semiconductor as mentioned above. The strong distortion in the donor packing of this salt would be responsible for the semiconducting property.

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3-6. Salts of C₂TET-TTF

The PF₆ salt and the ClO₄ salt of C_2 TET-TTF were obtained as black elongated plates by the electrochemical method. The compositions and crystal structures of these salts have not been determined yet. The resistivity of these single crystals were measured by the four-probe method. Both salts showed the room temperature conductivity of 10 S/cm. As shown in Fig. 3-21, each salt exhibited the metallic temperature dependence down to about 60 K for the PF₆ salt and about 80 K for the ClO₄ salt. The activation energy just below the transition was estimated to be 0.08, and 0.14 eV, respectively. The clear metal to semiconductor transitions in these salts present a striking contrast to the PF₆ and AsF₆ salts of C₁TET-TTF.

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3-7. Summary

In this chapter, the cation radical salts of C_TET-TTF were treated especially focusing on the C1TET-TTF salts. The PF6 and AsF6 salts of C1TET-TTF were isomorphic with characteristic anion deficiency. They showed the metallic temperature dependence of resistivity at least down to 240 K. Some kind of superlattice was observed in every C1TET-TTF salt structurally investigated, except for the Sb2F11 salt. The side-by-side intermolecular interactions were recognized in these cation radical salts, similarly to the neutral C1TET-TTF crystal. The interactions between the anion and the alkyl groups of the donor must influence the structure and physical properties of the salts. The appearance of the anion deficiency in the C.TET-TTF salts may indicate the flexibility of this donor molecule in its electronic states as well as in its structural aspects. If we could control the oxidation states of the donor molecule in solid state for example by the anion deficiency, we would be able to touch the band filling.

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Fig. 3-1. A two-compartment glass H-cell for elctrolysis.

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(a)

(b)



Fig. 3-3. (a) Side view of a stacking column of the donor molecules in (C₁TET-TTF)₂(PF₆)_{0.85}; (b) Mode of overlaps of C₁TET-TTF within the column.

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projected along the c axis. The dotted lines show short sulfur to sulfur distances $(3.54 \circ 3.68 \text{ Å})$.

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Fig. 3-5. Crystal structure of $(C_1 \text{TET-TTF})_2 (\text{AsF}_6)_{0.79}$ projected along the c axis. The dotted lines show short sulfur to sulfur distances (3.54 \sim 3.69 Å).

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Fig. 3-6. Molecular arrangement in $(C_1 \text{TET-TTF})_2 (PF_6)_{0.85}$ projected along the long molecular axis of the donor.

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Fig. 3-7. Molecular structure of $C_1 TET-TTF$ in $(C_1 TET-TTF)_2(AsF_6)_{0.79}$, (a) top view; (b) side view.

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Fig. 3-8. The temperature dependence of common logarithm of conductivity of the four C₁TET-TTF salts for the same crystals used in the EPR experiments (Fig. 3-10).

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Fig. 3-9. Angular dependence of g-factors and peak-to-peak linewidths (Δ H) of the C₁TET-TTF salts of PF₆ at room temperature. Closed symbols are for a crystal grown in methanol, open ones are for a crystal grown in ethanol. The lines drawn are visual guides.

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Fig. 3-11. The temperature dependence of common logarithm of conductivity of the $\rm I_3$ and $\rm AuI_2$ salts of $\rm C_1TET-TTF.$

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Fig. 3-12. (a) The temperature dependence of relative EPR intensity of the I₃ salt of C₁TET-TTF; (b) The temperature dependence of relative EPR intensity of the AuI₂ salt of C₁TET-TTF; (c) ln(IT) vs. 1/T plots for the AuI₂ salt of C₁TET-TTF.

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(C1TET-TTF)4Sb2F11.

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Fig. 3-17. The crystal structure of $(C_1 \text{TET-TTF})_4 \text{Sb}_2 \text{F}_{11}$ projected along the b axis.

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Fig. 3-18. The crystal structure of $(C_1 \text{TET-TTF})_4 \text{Sb}_2 \text{F}_{11}$ projected along the c axis. The solid and dotted lines show the sulfur to sulfur distances of 3.38 $^{\circ}$ 3.60 Å and 3.67 $^{\circ}$ 3.70 Å, respectively.

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Fig. 3-19. The contacts between the fluorine atoms of the anion and the carbon atoms of alkyl groups. The solid and dotted lines show carbon to fluorine distances of 3.02 Å and 3.12×3.34 Å, respectively.

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Sb02-F 5	1.830(17)	Sb2-F5	1.925(17)
-F01	1.832(13)	-F1	1.899(12)
-F03	1.842(17)	-F3	1.906(12)
-F02	1.873(12)	-F2	1.821(15)
-F04	1.894(13)	-F4	1.759(15)
-F06	1.879(9)	-F6	1.728(17) Å

Fig. 3-20. The structure of the ${\rm Sb_2F_{11}}$ anion in (C1TET-TTF) $_4{\rm Sb_2F_{11}}$.

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Fig. 3-21. The temperature dependence of resistivity of the ${\rm PF}_6$ and ${\rm ClO}_4$ salts of ${\rm C_2TET-TTF}.$

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Table 3-1. The conducting properties of $C_n^{\text{TET-TTF}}$ (n=1 and 2) salts. The resistivities were measured by the four probe method with gold paste as contacts except that the ReO₄, IBr₂, and Br salts were measured by the two probe method. T_{\min} refers to the temperature at which the resistivity comes to the minimum. The composition (D:X) is the value estimated by EPMA.

n	anion(X)	D:X	σ _{rt} (S/cm)	
	PF ₆	2:~0.8	10	metallic
	AsF ₆	2:~0.8	10	metallic
	Sb2F11	4:1	0.4	E_=0.16 eV
	Cl04	3:2	2.5	E_=0.09 eV
1	Re04	1:1	9x10 ⁻⁶	E_=0.21 eV
	I ₃	1:~0.8	30	T _{min} =100 K
	IBr ₂	1:1	1×10^{-5}	E_=0.20 eV
	Br	1:1	6.5x10 ⁻³	E_=0.15 eV
	BF4		1.5	E_=0.63 eV
	AuI2	1:~0.8	60	T _{min} =250 K
2	PF ₆		10	T
	ClO ₄		15	T _{min} =80 K

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Table 3-2. Atomic parameters of $(C_1 \text{TET-TTF})_2 (PF_6)_{0.85}$ grown in methanol. $B=(4/3) \sum_{j=1}^{2} a_j^a a_j$

	ALON	X	Y	7	R	1221	AT	
1	P1	0.0	0.0	0.5000	10 89	2	0 32	
2	P2	0.0	0.0	0.0	9.05	2	0.10	
3	F1	-0.0859	0.0290	0.2970	13.96	i	0.10	
4	F2	0.0439	-0.1168	0.2462	16.58	3	0.85	
5	F3	0.0411	0.0800	0.3007	16 10	7	0.85	
6	S1	0.4923	0.3698	0.1734	1 95		1.00	
7	\$2	0.5129	0.1239	0.2925	3 01		1.00	
8	\$3	0.6480	0.2941	-0.1962	5 01	-	1.00	
9	54	0.6708	0.0013	-0.0578	4.48	-	1.00	
10	\$5	0.3161	0.4775	0.5596	4.48	1	1.00	
11	56	0.3399	0.2328	0.6978	3.82	1	1.00	
12	\$7	0.1555	0.5973	0.9209	7.55	1	1.00	
N	ATOH	x	Y	7	2	100		
13	\$8	0.1799	0.3146	1.0625		1.31		
14	C1	0.5802	0.2487	0.0105	- 2 26	1	1.00	
15	C2	0.5902	0.1381	0.0634	7 20	-	1.00	
16	C3	0.7418	0.1580	-0.2484	10.05	1	1.00	
17	C4	0.7512	0.0563	-0 1950	11 05	-	1.00	
18	C5	0.2383	0.4674	0 7901	11.05	1	1.00	
19	C6	0.2481	0 1510	0 8461	4.00	1	1.00	
20	C7A	0.0742	0 6040	0.6461	3.03	1	1.00	
21	C78	0.1169	0 6746	0.6672	10.30	1	0.40	
22	C8	0.1123	0.2514	0 2021	0.04		0.54	
23	C 9	0.4507	0.2777	O TARA	7 76	1	1.00	
24	C10	0.3787	0.3219	0.5094	3.36	-	1.00	

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Table 3-3. Atomic parameters of $(C_1 \text{TET-TTF})_2 (PF_6)_{0.94}$ grown in ethanol. B= $(4/3) \sum_{ij} a_i a_j$

н	ATOH	X	Y	Z	8 1	SF	AI
1	P1	0.0	0.0	0.5000	5.84	2	0.47
2	F1	-0.0882	0.0291	0.3237	7.69	3	0.94
3	F2	0.0440	-0.1186	0.2749	7.78	3	0.94
4	F3	0.0394	0.0808	0.3355	8.05	3	0.94
5	S1	0.4914	0.3715	0.1791	3.29	1	1.00
6	\$2	0.5131	0.1240	0.2930	3.22	1	1.00
7	\$3	0.6463	0.2978	-0.1944	4.30	1	1.00
8	S4	0.6703	0.0025	-0.0620	3.92	1	1.00
9	\$5	0.3160	0.4774	0.5731	3.70	1	1.00
10	\$6	0.3419	0.231>	0.7024	3.32	1	1.00
11	\$7	0.1554	0.5931	0.9408	6.24	1	1.00
12	\$8	0.1837	0.3118	1.0835	4.54	1	1.00
N	ATON		v	7			
17	C1	0 5796	0 3500	0.0111	2 60	- ar	1 00
14	62	0.5700	0.2300	0.0111	2.07	1	1.00
15	67	0.3000	0.1393	0.0832	2.03	1	1.00
1.5	C.4	0.1312	0.1581	-0.2233	1.19	1	1.00
17		0.7551	0.0518	-0.1519	8.02	1	1.00
11	65	0.2380	0.4500	0.8008	3.32	4	1.00
18	60	0.2512	0.3514	0.8601	2.96	4	1.00
19	CTA	0.0734	0.6007	0.6714	7.43	4	0.45
20	C78	0.1251	0.6765	0.6916	6.75	4	0.55
21	65	0.1155	0.2479	0.8412	7.64	4	1.00
22	63	0.4508	0.2776	0.3447	2.56	4	1.00
23	C10	0.3780	0.3227	0.5155	2.62	4	1.00

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anion	P	F ₆	AsI	6	
solvent used	MeOH	EtOH	MeOH	EtOH	
space group	PĨ	PĪ	PĨ	PĪ	
a/Å	15.859(4)	15.768(3)	15.980(2)	15.948(2)	
b	11.601(4)	11.563(1)	11.625(2)	11.587(2)	
с	4.880(5)	4.938(1)	4.8893(8)	4.9262(10)	
a/°	100.12(5)	100.14(1)	99.94(2)	99.90(2)	
ß	92.53(5)	92.24(2)	92.39(2)	92.16(2)	
γ	72.51(2)	72.70(1)	72.68(1)	72.74(1)	
V/Å ³	843(1)	846(3)	854.1(2)	856.3(3)	
d _{calc} /gcm ⁻³	1.77	1.79	1.79	1.79	
dobs/gcm ⁻³	1.76			1.83	
R	0.073	0.072	0.079	0.064	
Z	1	1	1	1	
D:X	2:0.85	2:0.94	2:0.79	2:0.79	

Table 3-4. Crystallographic data of the $\rm C_{1}\, \rm TET-\rm TTF$ salts at room temperature.

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Table 3-5. Bond lengths of $\rm C_1 TET-TTF.$ The bond lengths are averaged by assuming $\rm C_{2v}$ symmetry.

compound	bond length/A								
	1	2	3	1	5	6	7		
neutral molecule I	1.339(4)	1.329(5)	1.338(5)	1.755	1.756	1.734	1.76		
neutral molecule II	1.350(5)	1.335(5)	1.333(5)	1.756	1.756	1.761	1.75		
(C ₁ TET-TTF) ₂ (AsF ₆)0.79	1.334(7)	1.343(8)	1.343(9)	1.751	1.750	1.741	1.74		
(C ₁ TET-TTF) ₂ (PF ₆) _{0.85}	1.331(14)	1.314(16)	1.297(17)	1.750	1.746	1.756	1.77		
(C ₁ TET-TTF) ₂ (PF ₆) _{0,94}	1.366(12)	1.309(14)	1.295(15)	1.741	1.742	1.752	1.76		

Table 3-6. The occupancies of the anions in the $\text{C}_{1}\text{TET-TTF}$ salts.

	5			
	Me	OH	Et	OH
site	PF ₆	AsF ₆	PF ₆	AsF ₆
0,0,1/2	0.64	0.61	0.94	0.79
0,0,0	0.21	0.18	0	0
total	0.85	0.79	0.94	0.79



Table 3-7. Crystallographic data of (C1TET-TTF)4Sb2F11.

Chemical Formula	C40 ^H 40 ^S 32 ^{Sb} 2 ^F 11
F.M.	1999.35
D:X	4:1
Crystal system	triclinic
Space group	P1
a/Å	15.645(5)
b	13.396(4)
c	8.943(2)
a/°	81.95(2)
β/	83.45(3)
γ/	69.43(2)
V/Å ³	1733(1)
Z	1
d _{calcd} /gem ⁻³	1.914
dobs/gcm ⁻³	1.94
R	0.062

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Table 3-8. Atomic parameters of (C1TET-TTF)4Sb2F11.

*0	ATOM	x	Ŧ	z	811 DR 8	822	833	812	813	823	5	ITAL
1	1 5	0.02074	0.01065	0.51041	0.015125	0.02+383	0.018499	-0.013876	0.002841	0.000275	1.000	3
2	\$802	0.02900	0.04654	0.30545	0.003999	0.005761	0.013490	-0.002017	0.007203	-0.002755	1.000	1
2	F 04	-0.08440	0.05325	0.24150	0.001904	0.008823	0.013524	-0.002225	-0.004052	-0.005746	1.000	3
-	F 03	-0.02337	0.18550	9.35352	0.005479	0.011110	0.053391	-0.003431	0.003033	-0.011585	1.700	3
1	F 02	0.14670	0.01951	0.15511	0.003988	0.012260	0.012547	-0.002717	-0.004410	-0.007:19	1.000	3
7	F 04	0.06281	0.09307	0,10442	0.025711	0.009059	0.007227	-0.001435	0,004434	0.004434	1.000	3
8	58 2	-0.02854	-0.04571	0.49677	0.003722	0.005058	0.010458	-0.001477	0.001328	-0.000454	1.000	1
,	7 4	0.08015	-0.04143	0.752-0	0.010040	0.010077	0.035329	-0.003511	0.008019	-0.007800	1.000	3
10	1 3	0.01890	-0.17445	0.66974	0.007980	0.004768	0.031714	-0.002198	0.004550	-0.005834	1.020	3
	1 1	-0.08+01	0.07585	0.75247	0.008517	0.003001	0.026180	0.000367	0.202745	-0.004744	1.000	-
- 1	1 1	-0.05150	-0.08902	0.88111	0.012027	0.015129	0.019401	0.000771	-0.007441	-0.004141	1.000	ĩ
14	5 04	0.30877	0.32824	0.97498	0.004542	0.006767	4.014738	-0.002507	0.003397	-0.003777	1.000	2
:5	\$ 05	0.48472	0.22493	0.74653	0.002489	0.004129	0.011748	-0.001077	0.000989	-0.002700	1.000	2
25	5 66	0.49729	0.29188	0.22134	0.003983	0.004217	0.014503	-0.001910	0.001141	-0.000279	1.000	2
17	5 07	0.52012	0.42692	0.69955	0.004867	0.003002	0.013444	-0.000855	9.071448	-0.000473	1.000	2
	5 08	0.43431	-0.02127	0.20102	0.0058457	2 004014	0.012377	-0.003723	0.003178	-0.007611	1 888	
22	\$013	0.29345	0.18799	0.51615	0.006556	0.00+195	0.015618	-2.223776	0.004414	-0.00+412	1.020	2
21	5014	0.13402	0.27328	0.7-24	0.010677	0.014025	0.015495	-0.008055	0.002171	-0.007790	1.000	2
22	\$015	0.14442	0.41211	1.19234	0.007242	0.010250	0.022308	-0.005021	0.007179	-0.005562	1.909	2
21			0.21711		0.005355	8.00777*	4. 21 15 2 3	-0.003528		-0.001041	1.000	,
24	5019	0.47484	0.35824	0.44140	0.004305	8.094933	0.013434	-0.001980	0.202673	0.001317	1.000	2
25	\$072	0.43449	0.11-49	0.53517	0.005833	0.007071	0.016278	-0.003417	0.000545	-0.001754	1.000	2
24	\$930	0.32469	0.39523	0.45454	0.005340	0.004474	0.013532	-0.001202	0.092237	-0.000431	1.000	z
27	2031	0.17426	0.50249	0.47787	0.00+507	0.008403	0.013865	-0.003057	0.001049	-0.004688	1.000	2
28	5032	0.19357	0.63601	1.15133	0.004788	0.006378	0.015228	-0.001294	0.003124	-0.003084	1.000	2
3.0	6012	0.23975	0.67.83	1.08753	0.004955	0.005157	0.007780	-0.000775	-0.007477	0.001443	1.000	
31	C024	0.21938	0.29443	0.41258	0.005124	0.007040	0.001874	-0.000767	0,000715	-0.005219	1.000	4
32	C033	0.59036	0.13115	0.59458	0.009483	0.003009	0.026567	-0.000174	-0.001444	-0.004605	1.000	4
33	C346	0.57761	0.23337	0.61638	0.001421	9.005046	0.00+030	3.000082	0.001147	0.001169	1.000	-
34	Cost	0.54324	0.19537	0.10407	0.001359	0.004214	0.003474	-0.001907	-0.000339	-0.000941	1.010	
35	C040	0.34230	0.1+111	0.14823	0.004410	0.001714	0.004117	-0.003232	0.002273	-0.000325	1.000	-
37	C041	9.43555	9.21534	9.31914	9.002403	0.005320	9.001474	-0.001279	-0.000780	-0.002371	1.700	4
3.5	C042	9.34337	0.24-32	0.40991	0.002060	0.005041	0.027327	-0.007035	-0.007237	-0.000302	1.010	4
37	C043	0.38277	0.40183	0.88779	0.00+053	0.007116	0.013433	-9.004727	0.002738	-0.002713	1.000	4
40	C044	0.45209	0.35388	0.78901	0.003871	0.007927	8.904774	-0.001348	-0.001276	-0.001166	1.000	4
*1	C043	0.25834	0.32313	1.05642	0.007540	8.003713	0.016034	-0.005740	0.004496	-0.006775	1.000	
43	C267	0.11644	6.14784	0.57.34	0.011759	0.018170	0.035719	-0.015070	0.011103	-0.010719	1.000	2
44	C048	0,70302	0.00480	-0.24763	0.005758	0,004728	0,013977	-0.001550	0.005128	-2.006653	1.000	
45	C069	0.74330	0.07204	-0.00011	0.003431	0.004811	0.017431	-0.001894	0.000371	-0.003373	1.000	
44	C070	0.10838	0.73477	1.01008	0.013417	0.008671	0.023481	8.001954	-0.023244	0.000555	1.000	
47	C071	0.14744	0.28494	1.13527	0.012895	0.017411	0.038107	-0.014085	0.012791	-0.012049	1.000	-
4	C072	0.72876	0.14235	0.42733	0.005907	0.005755	0.009775	-0.002455	-0.000217	-0.001278	1.000	-
50	5 4	0.42004	0 47767	0.02133	0.004774	0.004218	0.014555	-0.002880	0.000975	-0.000110	1.000	,
51	5 5	0.51505	0.77474	0.25405	0.005274	0.004549	9.921719	-0. 203229	0.002471	-0.000044	1.000	2
52	5 6	0.50128	0.70278	0.77294	0.004513	0.005018	0.015576	-0.002134	0.002567	-0.00158:	1.000	2
53	\$ 7	0.48092	0.57113	0.29331	0.003087	0.004946	0.018782	-0.002433	0.003041	-0.003332	1.000	2
54	5 8	0.53201	0.7.479	0.71766	0.00-609	0.005788	0.016480	-0.002987	0.002822	-0.003407	1.020	2
33	5 11	0.37672	1.02701	0.92101	0.008880	0.004844	0.024918	-0.004318	0.009100	-0.007043	1.000	-
17	\$ 14	0.8618.	0.72782	0.24111	0.009594	0.013+68	0.011857	-0.009018	0.007479	-0.009076	1.000	2
52	\$ 15	0.85450	0.58495	-0.19629	0.004373	0.010+43	0.018494	-0.006087	0.004444	-0.005544	1.000	2
51	5 18	0.34234	0.77975	0.99503	0.004311	0.004514	0.013-99	-0.002254	0.003205	-0.001053	1.000	2
60	\$ 17	0.32244	0.43780	0.51772	0.003475	0.005524	0.022427	-0.002007	0.002544	-0.003-80	1.990	2
41	\$ 22	2.34195	0.38582	0.45771	0.004370	0.002441	0.017917	-0.000717	0.007841	-0.003-88	1.000	2
62	5 30	0.47171	0.60725	0.34148	0.003394	0.203750	0.013594	-0.002714	0.001437	-0.004431	1.000	
	\$ 32	0.80583	0.14267	-0.15591	0.004445	0.004411	0.012217	-0.003450	0.002318	-0.001344	1.000	2
45	\$ 33	0.64908	0.47380	0.05982	0.00-588	0.003927	0.022680	-0.002059	0.002213	-0,001247	1.000	ż
44	C 12	0.74494	0.54441	-0.07154	0.002555	0.006895	0.013247	-0.003329	0.004448	-0.004218	1.000	4
67	C 24	0.77671	0.70945	0.38+17	0.005405	0.008514	0.029635	-0.004143	0,004181	-0.002713	1.000	4
64	C 72	0.40743	0.67478	0.40114	0.004243	5.004481	0.004740	-0.001407	0.003962	0.002543	1.000	-
**	C 44	0.42772	0.76728	0.37986	0.003051	0.003804	0.023400	-0.003222	0.000490	-0.003439	1.000	
10	C 51	0.42121	0.81181	0.86231	0.001455	0.002784	-0.003052	-0.000233		-0.007975	1.000	-
72	C 40	9.76202	0.42124	0.43515	0.003773	8.011718	9.923247	-0.001442	0.004345	-0.011004	1.000	
73	C 41	0.57429	0.77997	0.48054	0.00+590	0.002221	0.035355	-0.001528	0.005222	-0.001300	1.000	-
74	C 42	0.++334	0.74235	0.58249	0.005285	0.004595	0.002529	-0.002157	0.003087	-0.001808	1.000	4
75	C 43	0.42408	0.40-80	0.10784	0.001900	0.002844	0.011741	-0.000404	0.001477	-0.000220	1.905	4
76	C 44	0.54944	0. += 230	0.2091.	0.003553	0.001203	0.029431	-0.002043	0.004226	-0.002512	1.000	4
77	C 45	0.74459	0.47744	-0.04678	0.003028	9.003102	0.004427	0.000345	0.000433	0.007114	1.000	-
-	C 47		0.14501	0.29957	0 216781	8 011930	0.023321	-0.010780	0.008797	-0.007093	1.000	
80	C 68	9.28210	0.77760	1.24443	0.004350	0.014957	0.051904	-0.004018	0.007338	-0.002467	1.000	-
81	C 69	0.25534	0.92155	0.99726	0.006781	0.010046	0.052926	-0.003544	0.012440	-9.012752	1.000	4
82	C 70	0.85060	0.28473	-0.01143	0.005746	0.010382	0.021923	-0.001489	-0.005313	-0.004901	1.000	4
#3	C 71	0.84788	0.71922	-0.17221	0.014833	0.010211	0.015701	-0.008099	2.004329	-0.005386	1.000	4
34	C 72	0.26815	0.84711	0.54408	0.004979	0.007439	0.041445	-0.002948	0.014070	-0.012449	1.000	4
85	C 73	0.23532	0.77679	0.31434	9.003444	0.008149	0.012751	0.000164	-0.003895	-0.003478	1.000	-

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Table 3-9. The isotropic thermal factors, $B_{eq}s$, of alkyl carbon atoms in $(C_1TET-TTF)_4Sb_2F_{11}$. The values for the PF_6 salts are also listed for comparison.

Beg=(4/3) \SEBijaiaj
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B _{eq} /Å ²							
		1	2	3	4		
	A	2.93	3.48	5.51	4.98		
Sb2F11	A'	8.93	9.77	3.69	6.09		
	В	12.43	2.37	9.21	5.49		
_	_B'		9.67	216	_ 5.73_		
a	verage	6.56	6.32	5.14	5.57		
PF ₆ -MeO	Н	11.85	10.05	9.02	7.56		
PF ₆ -EtO	н	8.62	7.79	7.64	7.43 6.75		

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Table 3-10.	Fo-Fc for (C1TET-TTF)4Sb2F11. Number of reflections=6774	
	Format:(h k l F F del)	

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	Format:	(n K I F	o c del)
7 -1 1 14 14 1 -1 -11			
* -* 1 17 17 * -11 -11	1 14 18 2 1	A 2 119 117 1	2 3 2 49 47 2
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3 -4 1 11 13 1 -5 -12	1791 0	8 1 79 78 8	-1 5 7 15 17 7
L -4 1 17 14 1 -7 -17	1 14 14 1 -1	A 1 14 17 1	-1 5 2 25 22 1
1 -4 1 34 37 1 9 12	2 51 5+ 2 -1	8 2 77 77 8	-5 5 7 24 25 8
-1 -4 1 51 51 1 4 54	1 25 28 2 -	4 1 27 27 8	- 5 2 25 25 1
-1 -4 1 11 14 1 4 11	1 29 30 1 -+	4 1 13 15 1	-1 1 1 37 34 1
	1 1 10 1 1+	7 2 44 45 3	-? 5 1 1? 24 1
		7 7 12 14 1	
-12 42 44 44 2 42 41-	1 22 22 1 1 9	7 2 29 24 2	13 4 2 9 19 1
-11 -4 1 16 27 1 9 11	1 23 25 8 7	7 2 55 57 3	11 + 2 8+ 82 1
-11 -1 1 11 11 1 1 1	7 11 11 0 1	7 1 10 10 1	
+ -+ 1 13 17 2 5 11	2 12 11 1 4	7 2 44 45 1	4 + 2 75 7+ 1
		7 7 11 11 14 1	
1 -1 1 17 17 1 1 11	1 10 11 1 1	7 2 44 47 1	1 . 1
1 -4 1 34 34 1 -1 11	1 24 28 2 8	7 2 44 44 8	3 + 1 19 29 1
	1 11 11 1 12	7 1 1 1 1 1	1 4 1 24 24 5
-1 -1 1 12 12 1 11 11	1 23 23 4 -3	7 7 12 12 1	4 4 2 18 17 1
-1 -7 1 14 14 1 13 13	1 25 25 5 -	7 7 7 75 74 1	-1 + 1 13 13 1
	1 11 14 1 -4	7 2 37 39 8	
	2 14 15 9 13	+ 1 17 15 1	-4 + 1 12 13 1
	7 24 27 4 15	· · · · · · ·	
	2 29 22 2 18		-4 6 2 33 35 2
-14 -9 1 24 11 1 -1 14	1 13 13 1 9	* 1 11 11 1	
-11 -+ 1 11 71 1 -1 11	2 44 44 2 7	4 2 39 41 2	-11 4 1 23 22 1
1 -18 1 11 11 1 - 18	1 11 1 1 1	* # 11× 11# *	1. 1 1 1
1 -14 1 79 77 1 12 7		* 1 ** 1* *	
8 -18 1 28 19 1 11 9	1 22 25 1 1	* 2 ++ +7 1	11 3 8 17 17 9
-1 -13 1 29 21 1 19 7		* 1 77 87 1	12 1 1 1 1 1 1
-1 -10 1 10 11 0 7 7	1 14 11 1 1	* 217517 *	1 1 1 77 75 1
	2 8 11 3 -1	* 2 31 33 2	7 3 2 78 78 4
	1 11 11 1 -1	A 2 11 18 4	1 1 1 4 4 1
27 -18 1 24 25 2 3 9	1 7 11 1		+ 3 2 31 31 8
-4 -14 1 43 41 1 1 1	1 11 11 1 -1	* 2 54 55 1	3 3 1 22 24 1
-18 -18 1 41 44 1 8 9	2 102 107 4 -7	+ 1 17 IB 1	
-11 -18 1 1 1 1 1 1	8 11 13 8 -4	* Z 19 18 F	
-11 -15 1 40 17 3 -1 7	7 10 17 1 -9	1 1 11 11 1	-1 1 1 17 18 1
1 -11 1 20 21 0 -5 9	1 30 31 3 13	5 1 11 11 1	- 1 2 45 43 2
· · · · · · · · · · · · · · · ·	7 34 31 7 11	1 1 14 14 1	-1 1 1 11 11 1
	7 47 47 1 7	1 1 17 14 1	-7 1 1 11 11 1
-1 -11 1 47 44 1 11 8	1 7 8 1 8	5 1 43 44 1	-4 3 2 132 134 4
	7 44 44 1	3 1 M3 M2 1	1 1 2 12 14 1
-7 -11 1 1 1 1 1 1 1	2 34 34 8 5	5 2 13 18 3	-11 3 2 47 47 1

Table 3-10. (continued)

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-1	-	1	24
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-	-	- 3	1.81
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-+	-	- 5	67
-7	-	3	
-	-	- 3	73
- *	-	1	2.5
-18	-	- 3	81
-11	-	1	3.2
-12	-	3	11
-12	-	- 1	1.5.6
	-5	- 3	12
	-5	1	22
7	-5	- 3	1.4
	-1	1	2.5
5	-5	- 5	15
3	-1	- 1	23
2	-5	- 3	
-	-1	- 5	
	-5	- 3	32
-1	-5	- 5	24
-2	-1	1	22
-3	-5	- 3	73
-	-5	1	2.4
-5	-5	- 3	47
-+	-5	3	53
-7	-5	1	37
-8	-5	3	55
- *	-5	- 3	\$5
-1.0	-1	- 3	52
-11	-5	1	27
-12	-5	- 3	1.4
-13	-5	3	12
	- 1	3	13
7	- 6	- 1	1.3
	-+	3	37
5	-6	3	1.0
3	- 5	3	1.4
2	-	- 3	1.2
1	- 5	- 1	13
	-+	3	25
-1	-+	3	53
-2	-+	3	55
-3	- >	3	12
		3	31
- 5	-	- 3	
-+	- 6	- 3	29
-7	-8	3	- 44
	-+	3	39
- 7		3	2.
-1.6	- 5	3	20
-11		3	34
-12		3	11
,	-7	3	11
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3	-7	3	14
	-7	3	1.

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Table 3-10. (continued)

3	-1	-	13	24	1	
	1	÷.	12	1.1	÷.	
-1		5	38	28	1	
-2		5	28	29	1	
-1	*	5	52	54	1	
-	•	2	37			
->		2				
	12		1.1		÷.	
-		1	17	17	1	
13	2	3	17	:.	2	
17	3	3	1.4	2.0		
11	3	3	11	34		
19	3	3	24	24	5	
		2	11		- S -	
	- 1	2				
		-	2.	14	1	
5	3	5	38	64	1	
3	3	3	23	25	1	
2	3	3	11	27	1	
- 1	- 2		11	11		
	-	2	-	10	1	
			12		÷.	
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Table 3-10. (continued)

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	2	14	14	2	17	1.	1	-7		2	1.0	14	-	14	-	1	1	12	:		-14	4	19	1.0	
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 Table 3-10. (continued) Format:(h k l F

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Table 3-10. (continued) Format:(h k l F_o F_c del)

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 Table 3-10. (continued) Format:(h k l F_o F_c del)

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 Table 3-10. (continued) Format:(h k l F_o F_c del)

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Table 3-10. (continued) Format:(h k l F_o F_c

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3-10. Table (continued)
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